

Axion in antiferromagnetic insulators

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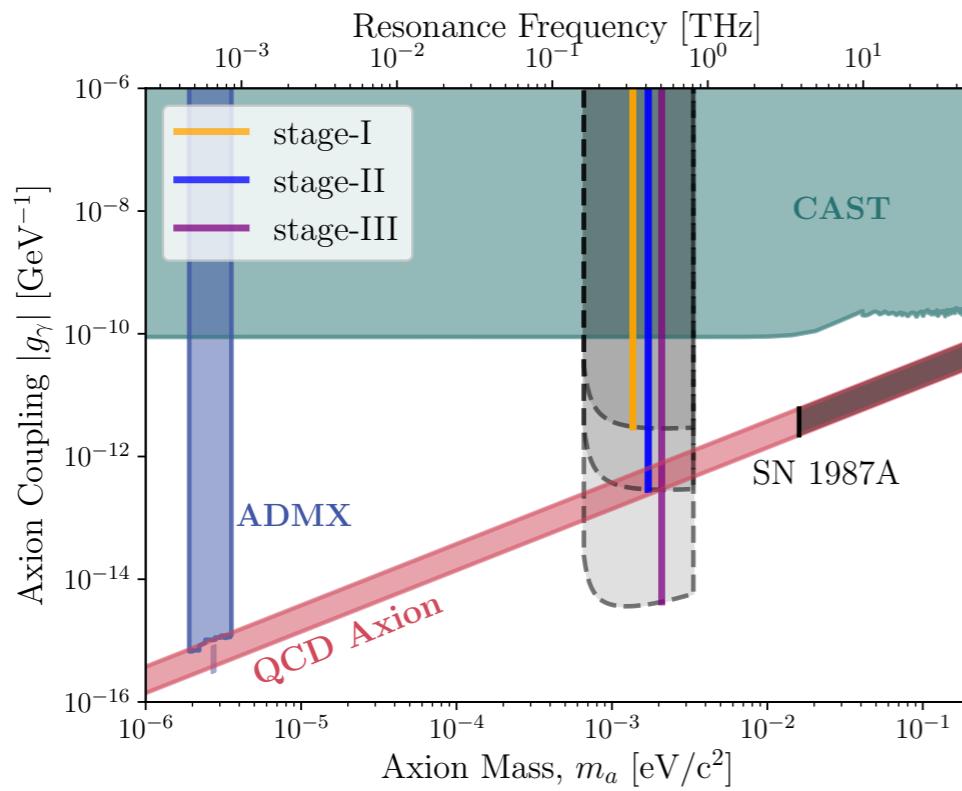
1. Introduction

Axion in condensed matter physics

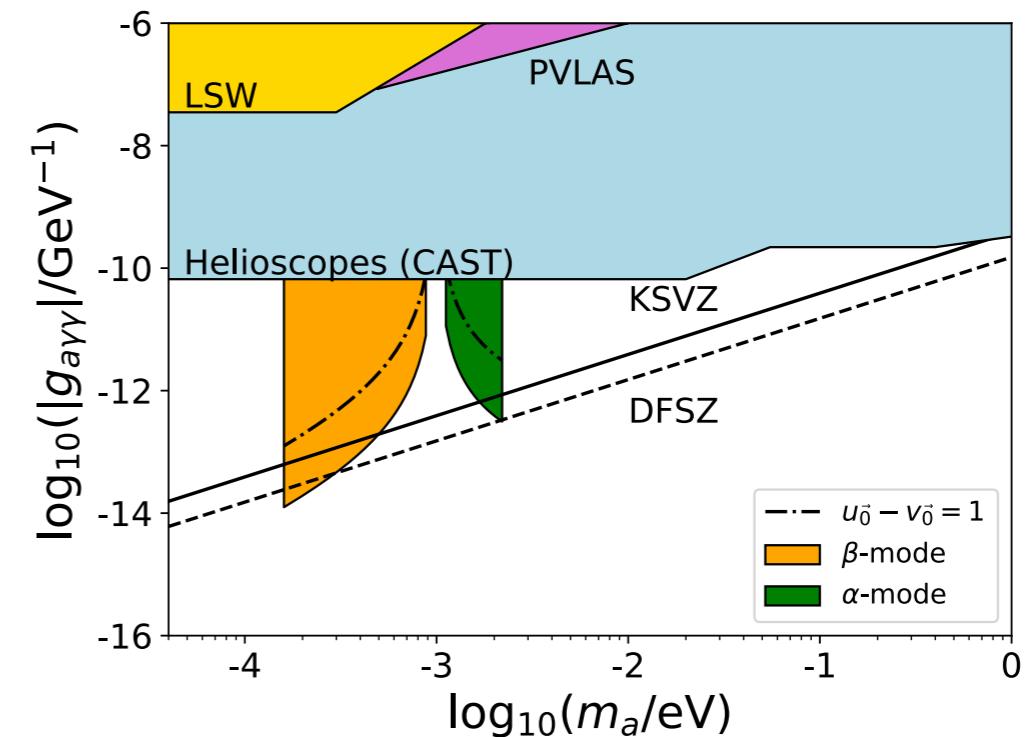
A hot topic and relates to

- Topological insulator
- Magnetoelectric effect
- Ferromagnetism / Antiferromagnetism
- It may be used in *particle* axion detection

Proposals to detect axion/axion-like particles (ALPs)



Marsh et al. '19



Chigusa et al. '21

Topological magnetic insulators are used

Dynamical axion is predicted in topological magnetic insulators

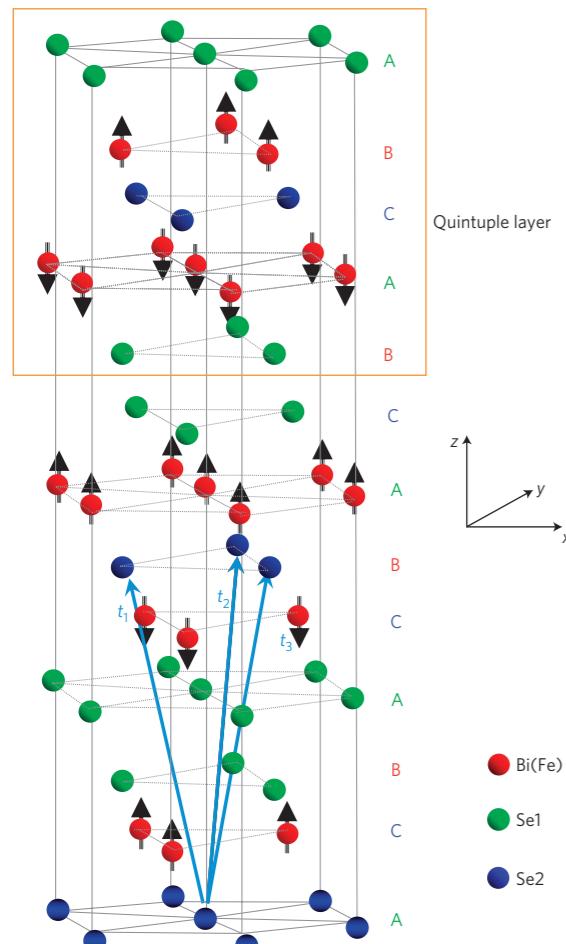
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nature
physics

Dynamical axion field in topological magnetic insulators

Rundong Li¹, Jing Wang^{1,2}, Xiao-Liang Qi¹ and Shou-Cheng Zhang^{1*}



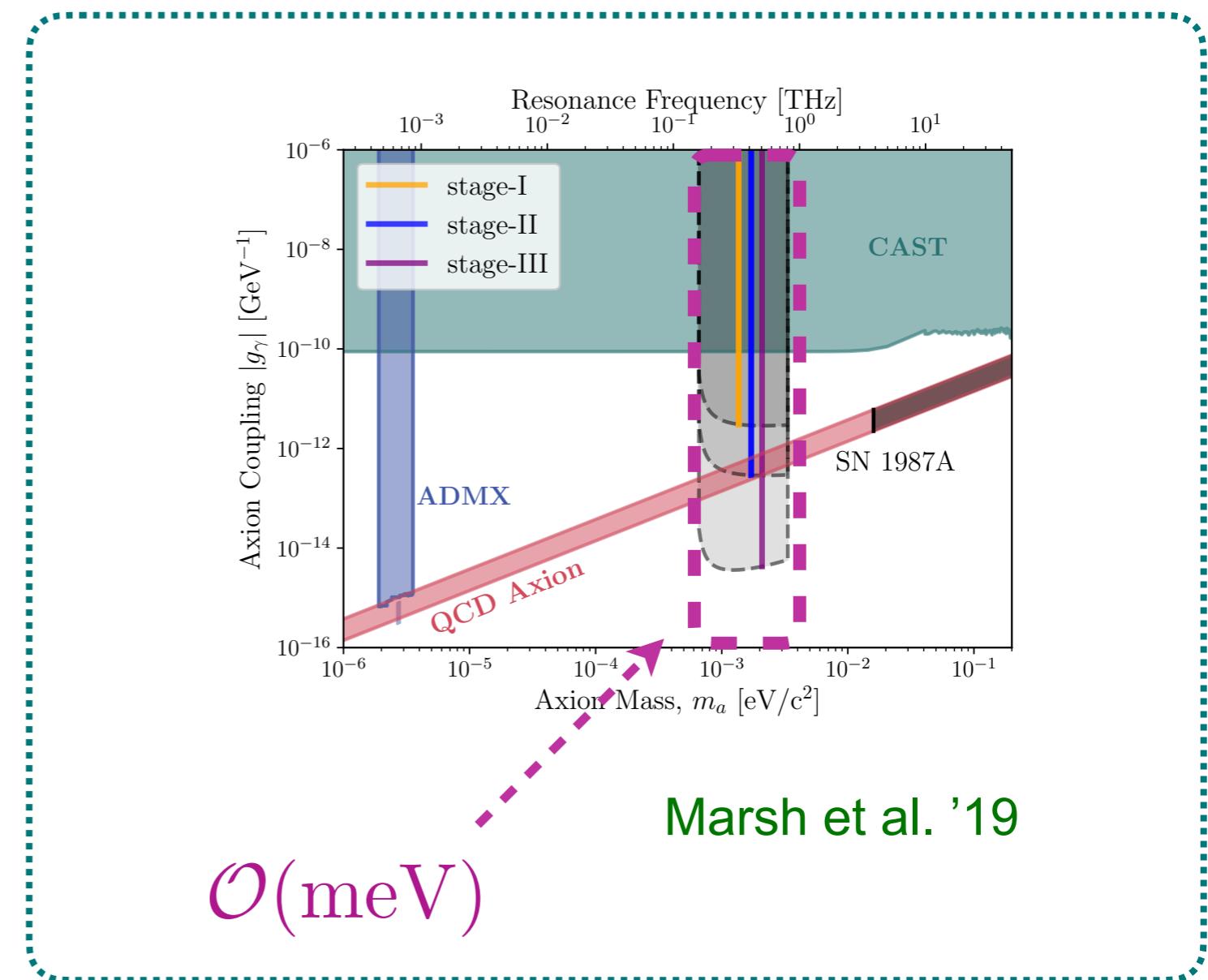
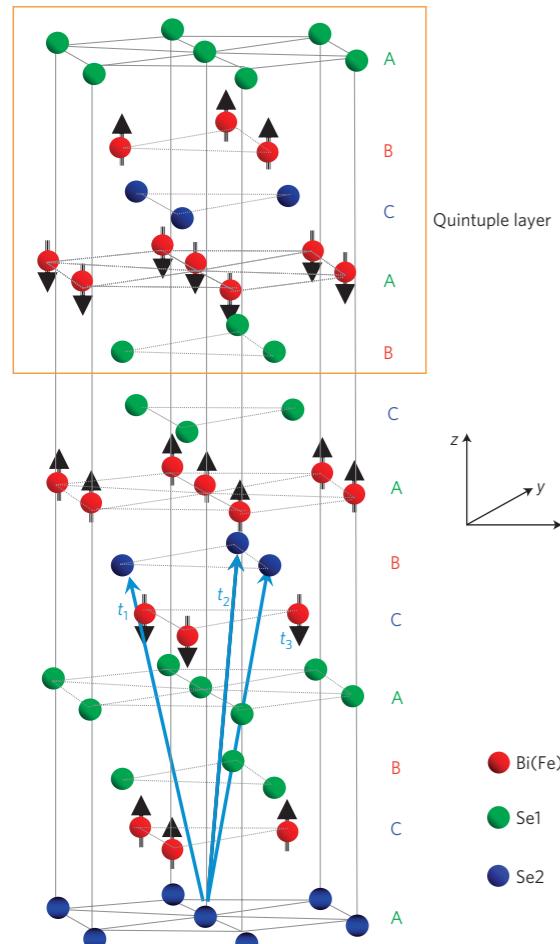
$$\begin{aligned} \mathcal{S}_{\text{tot}} &= \mathcal{S}_{\text{Maxwell}} + \mathcal{S}_{\text{topo}} + \mathcal{S}_{\text{axion}} \\ &= \frac{1}{8\pi} \int d^3x dt \left(\epsilon E^2 - \frac{1}{\mu} B^2 \right) + \boxed{\frac{\alpha}{4\pi^2} \int d^3x dt (\theta_0 + \delta\theta) E \cdot B} \\ &\quad + g^2 J \int d^3x dt [(\partial_t \delta\theta)^2 - (\nu_i \partial_i \delta\theta)^2 - m^2 \delta\theta^2] \end{aligned} \quad (4)$$

Axion mass $\sim \mathcal{O}(\text{meV})$

Bi_2Se_3 ← Topological insulator

Dynamical axion field in topological magnetic insulators

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Today, I would like to address

- What is topological insulator?
- How does antiferromagnetism play a role?
- How is axion in insulators described?

Plan to talk

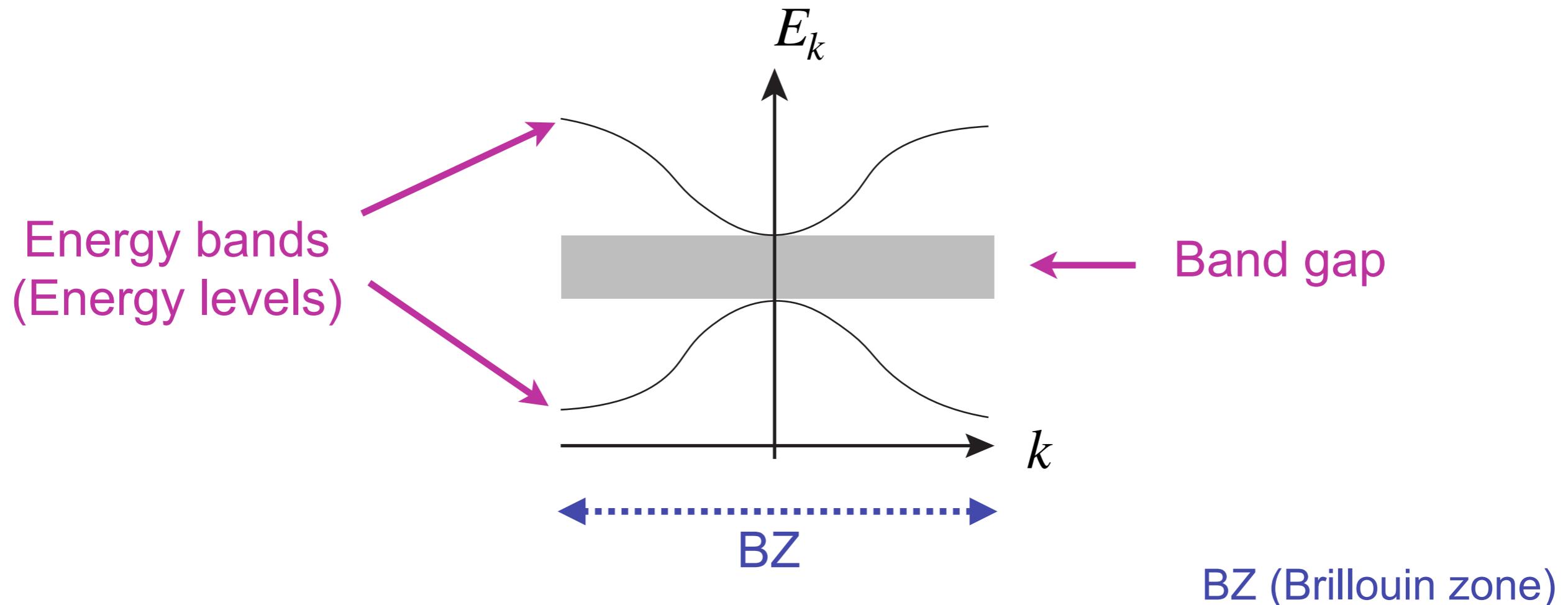
1. Introduction
2. Brief review of condensed matter physics (related to axion)
3. Axion in antiferromagnetic topological insulators
4. Conclusions

2. Brief review of condensed matter physics (related to axion)

Topics related to axion in condensed matter physics

- a). Insulators
- b). Quantum Hall effect
- c). Topological insulators

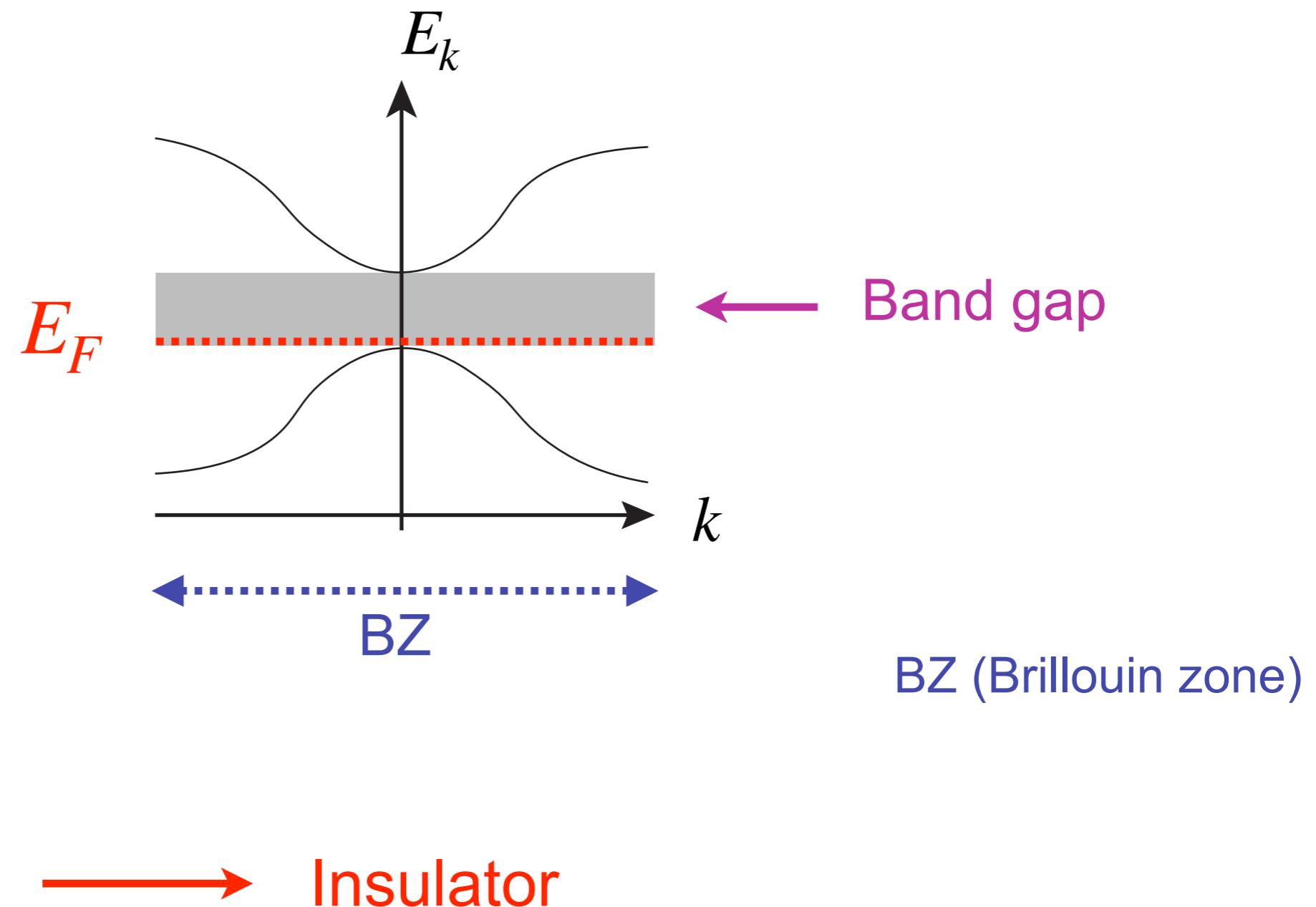
Minimum basics



E_k : energy of electron

k : wavenumber of electron

Minimum basics



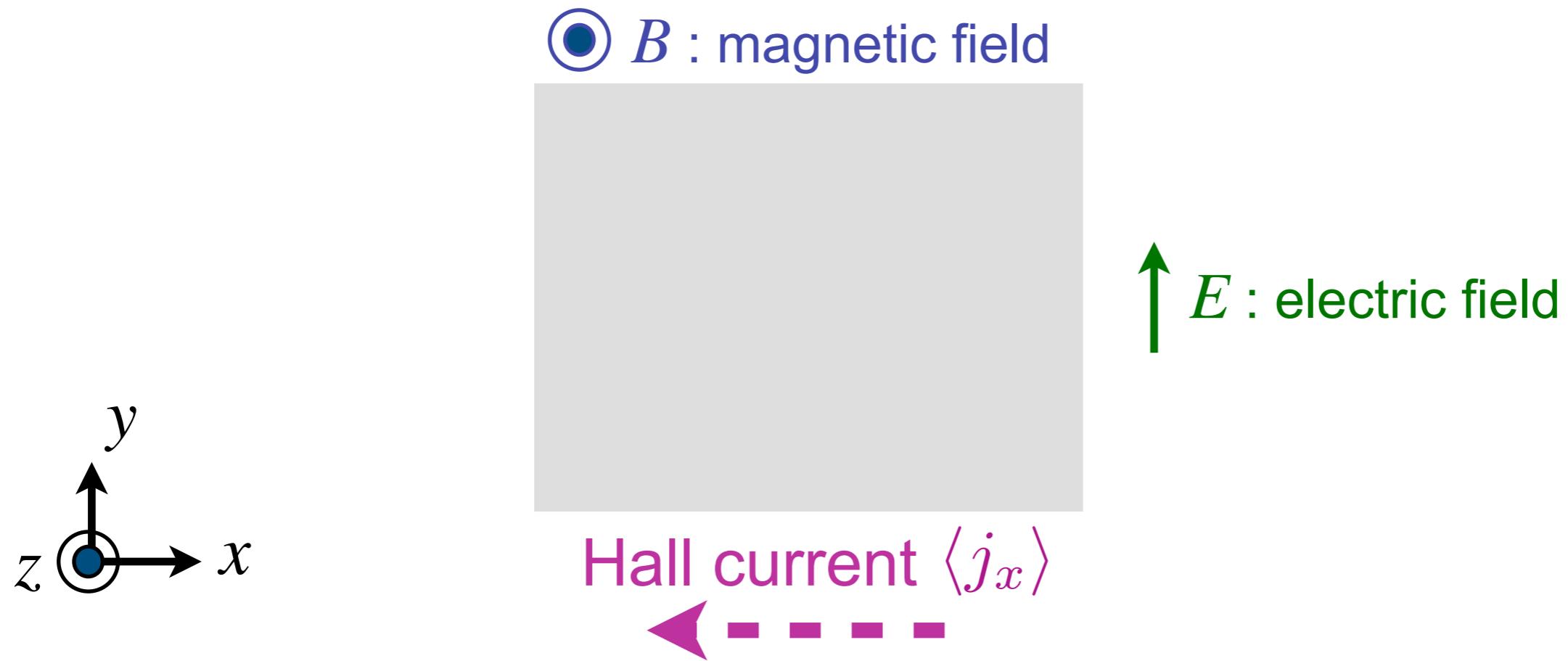
Quantum Hall (QH) effect

e.g., 2D insulator



Quantum Hall (QH) effect

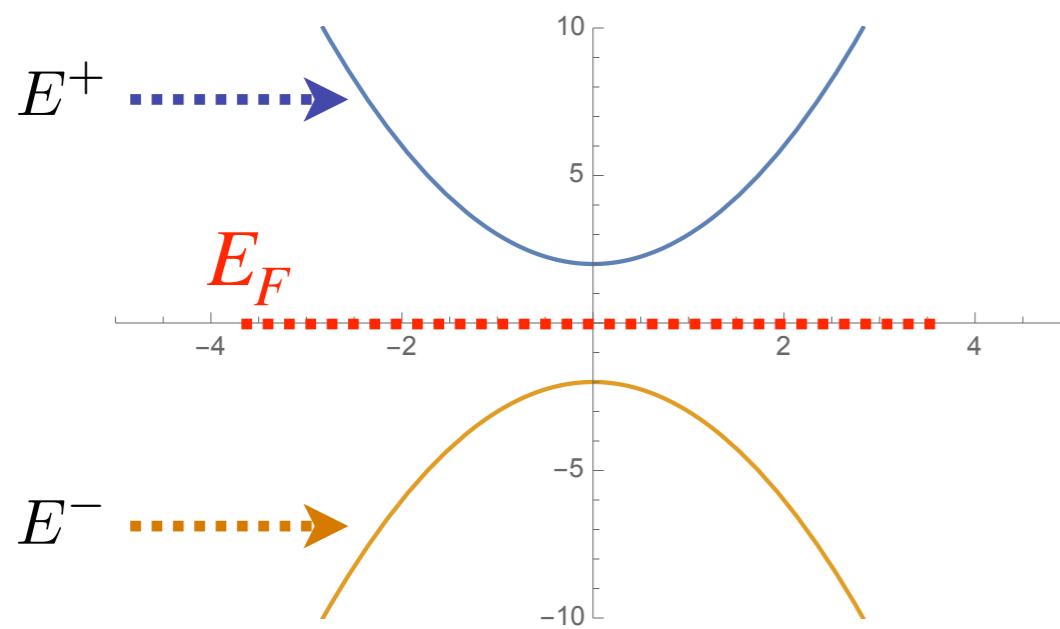
e.g., 2D insulator



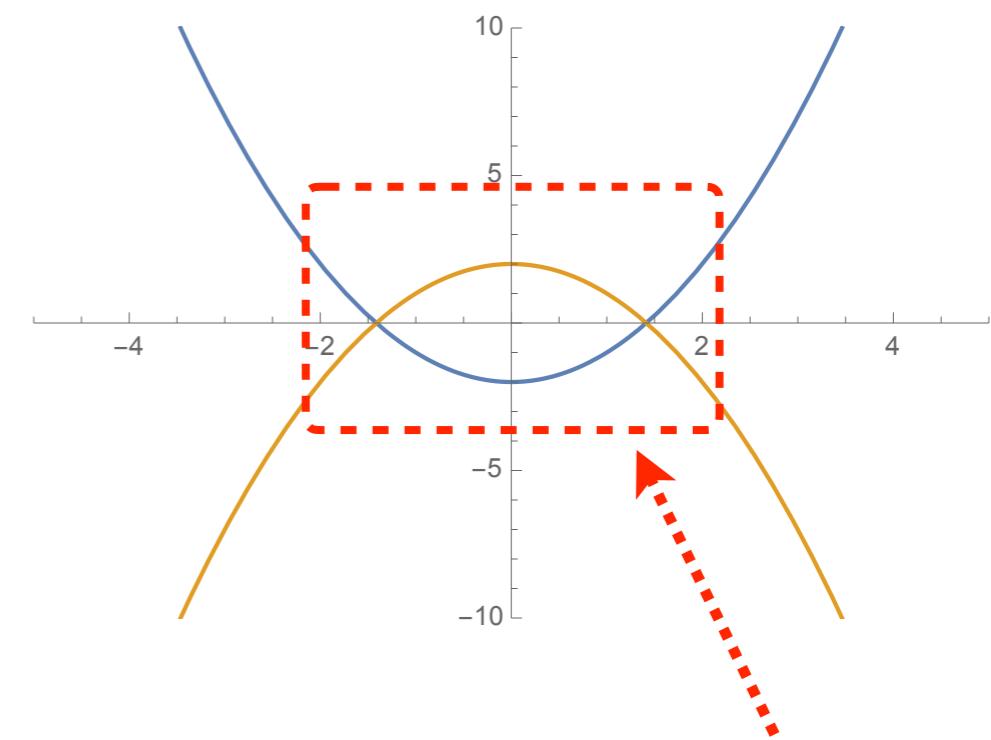
Quantized electric current is induced in x direction

“(Integer) QH effect”

The band structure



Normal insulator



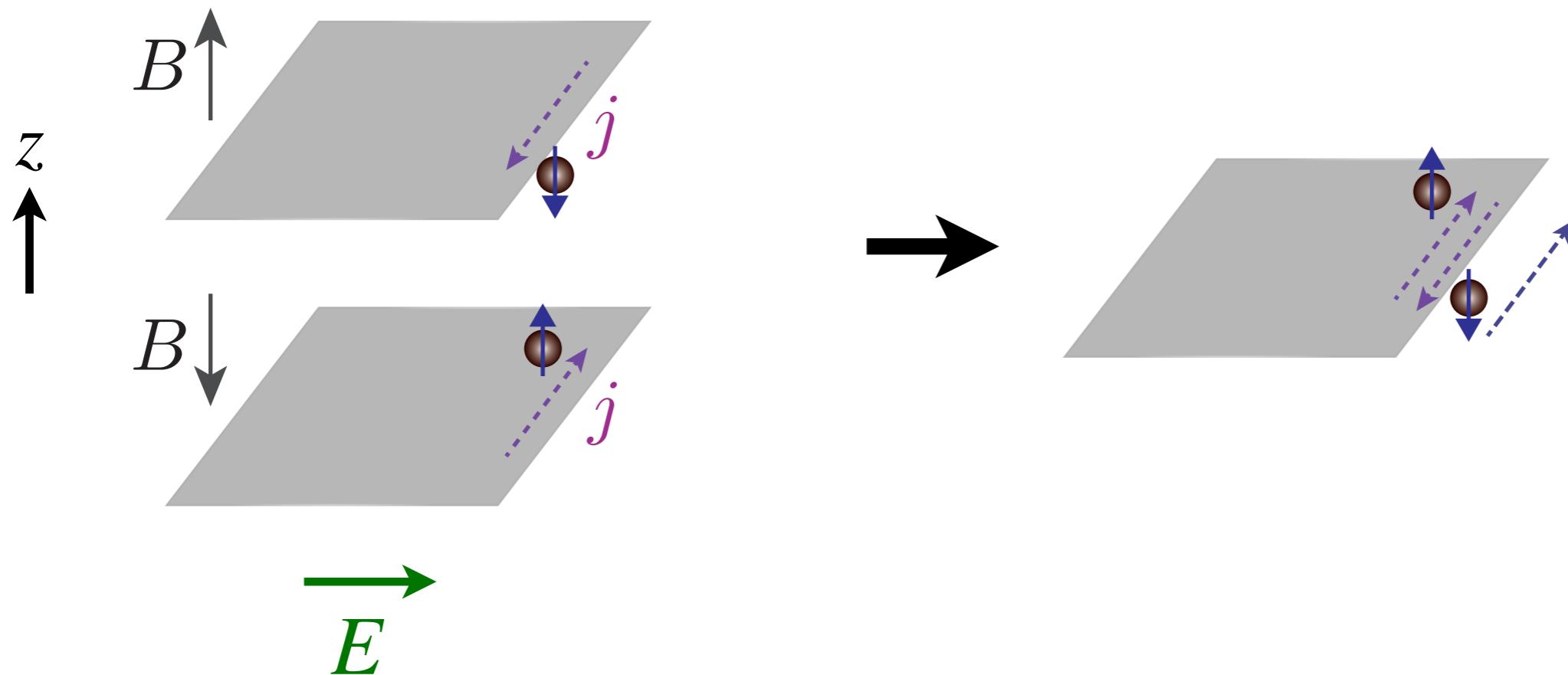
Band inversion

QH insulator

Topological insulators (TIs)

Idea: combination of two QH insulators

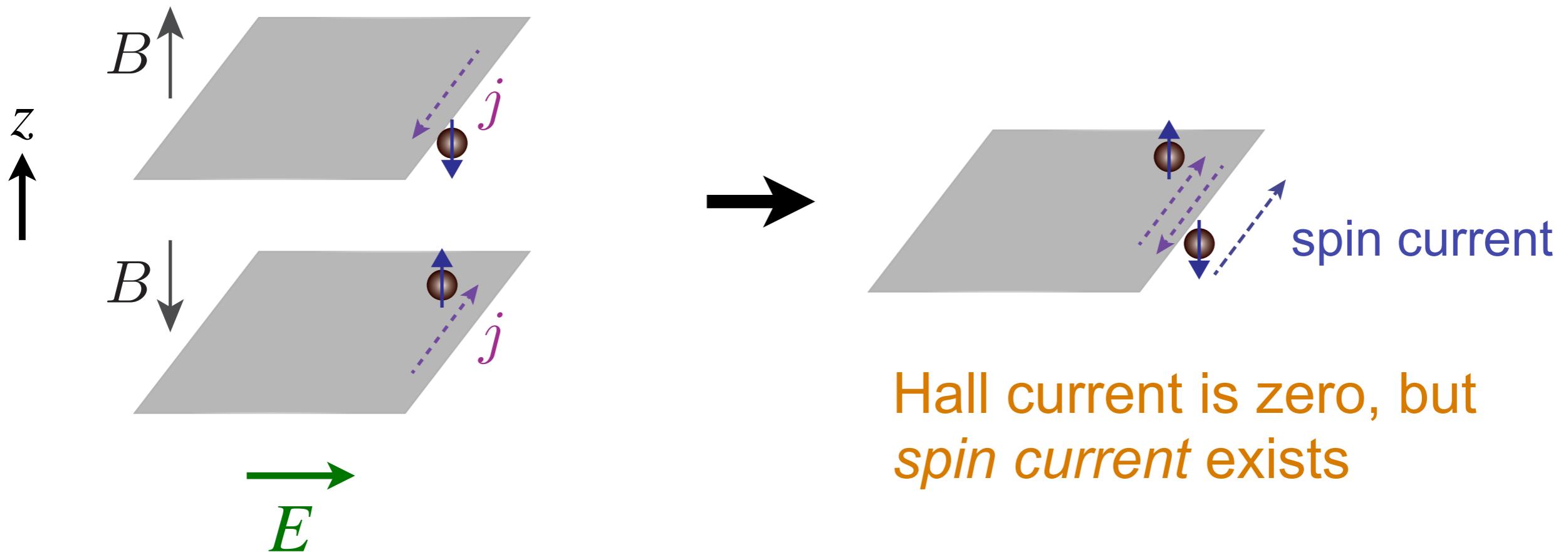
Kane, Mele '05



Topological insulators (TIs)

Idea: combination of two QH insulators

Kane, Mele '05

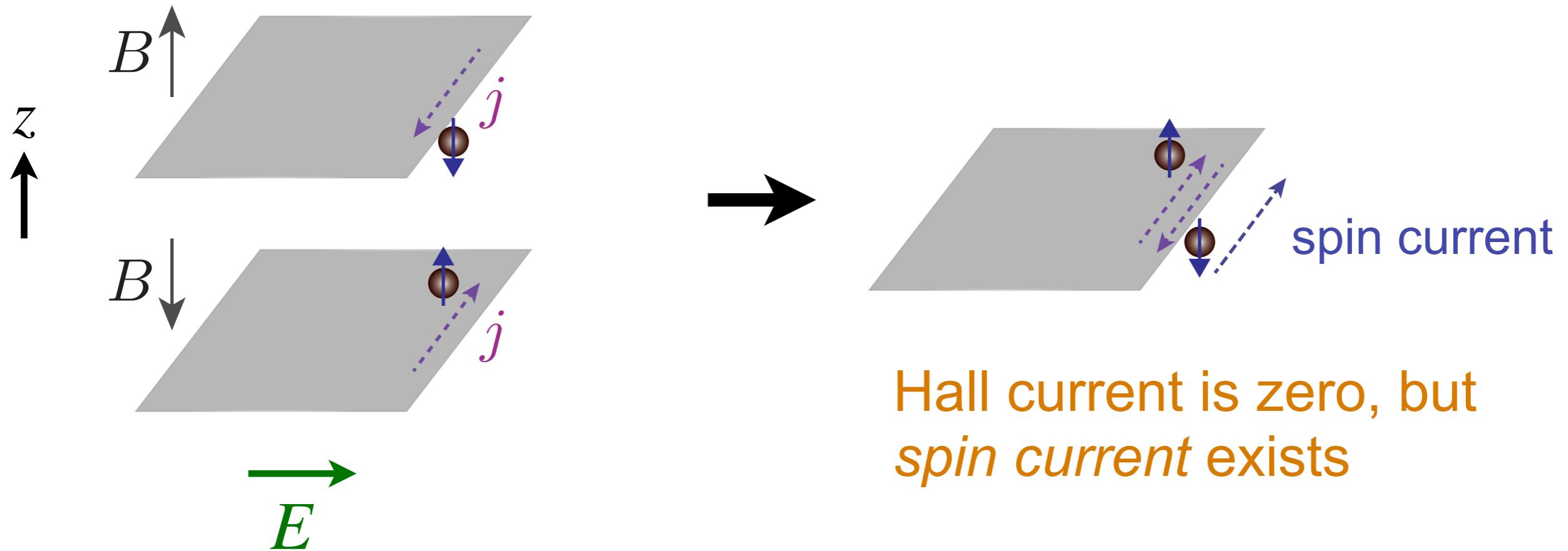


Hall current is zero, but
spin current exists

Topological insulators (TIs)

Idea: combination of two QH insulators

Kane, Mele '05



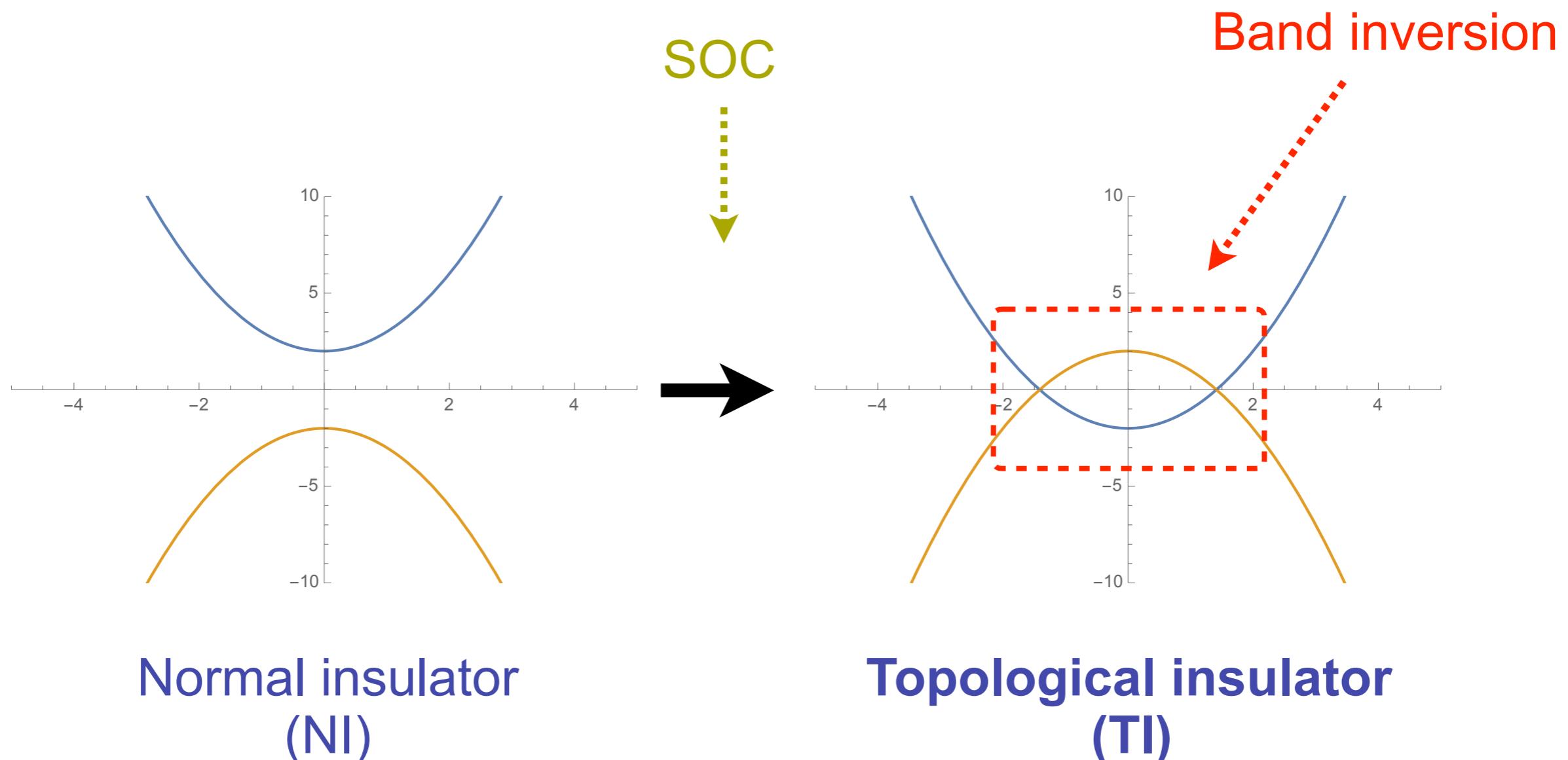
Hall current is zero, but
spin current exists

Such a system can be realized due to SOC
(without magnetic field)

SOC: spin orbit coupling

The band structure

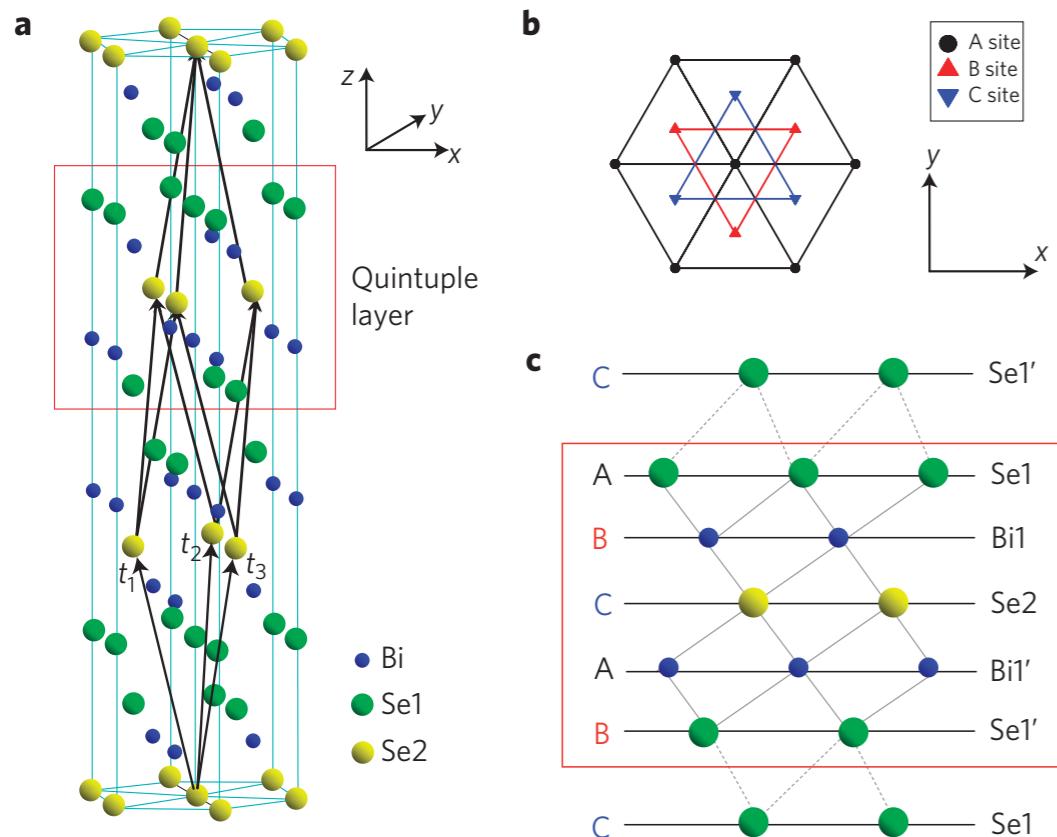
→ The same as QH insulators



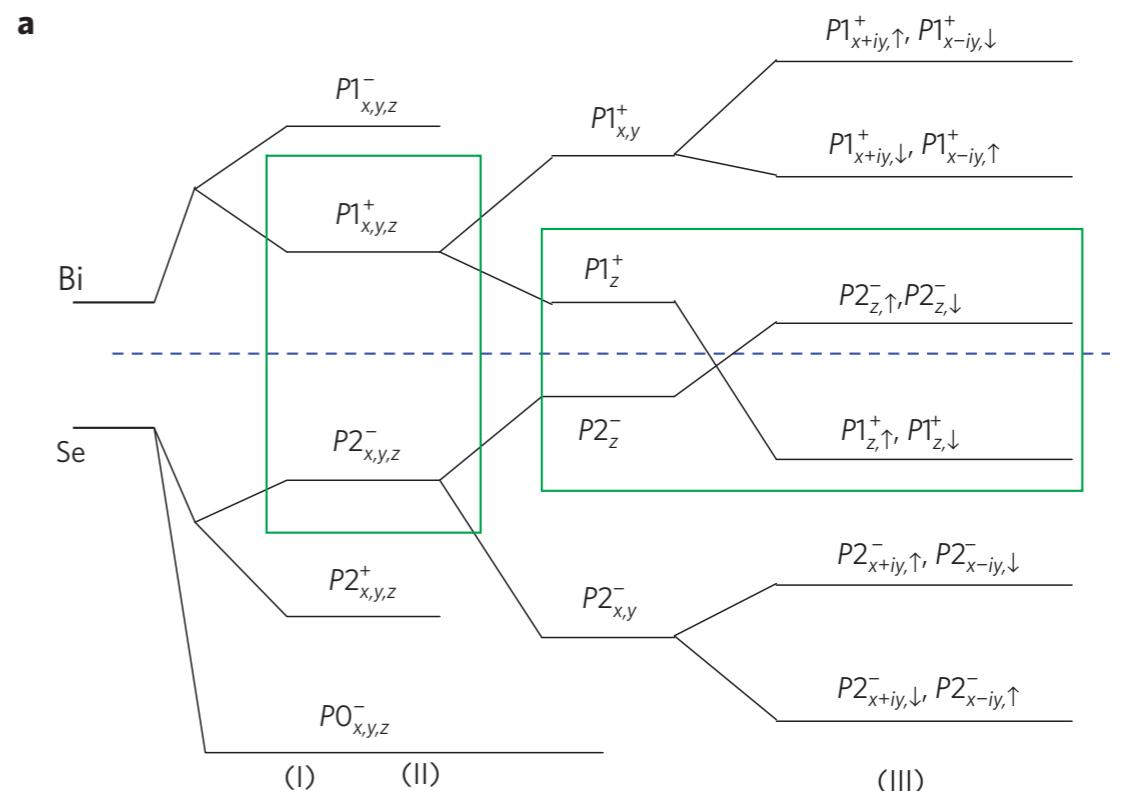
3. Axion in antiferromagnetic topological insulators

Let's consider 3D TI, Bi_2Se_3

H. Zhang et al. '09



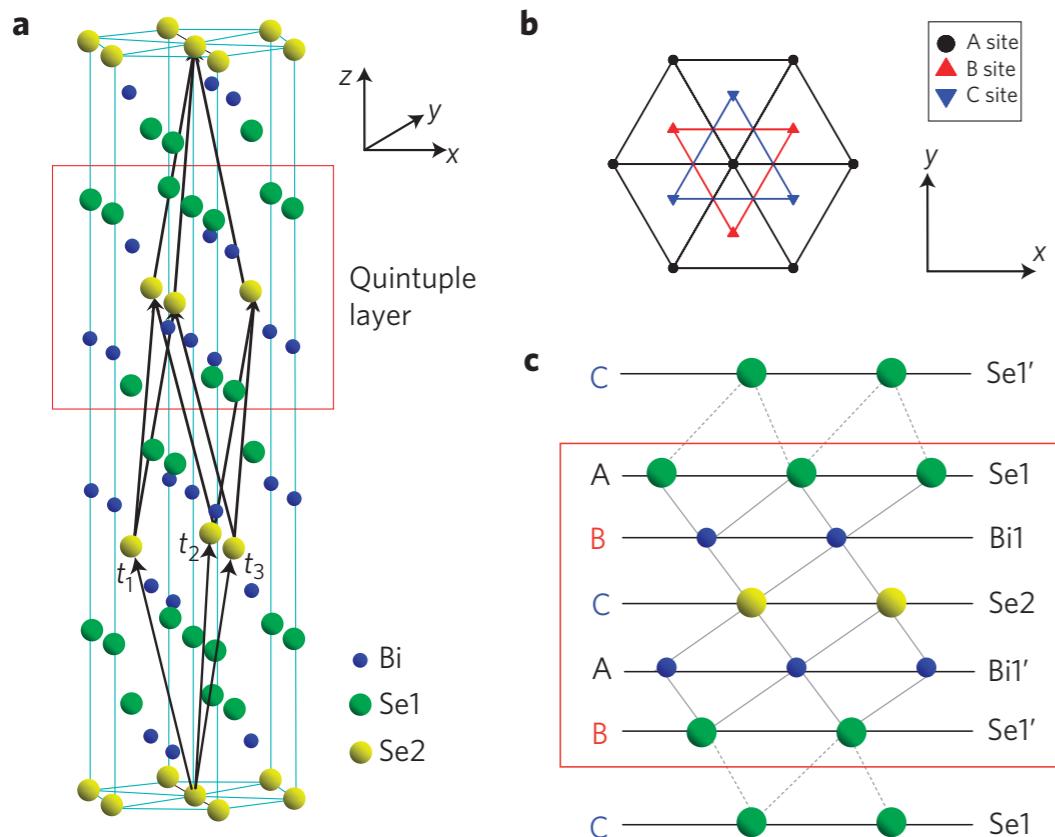
Cristal structure



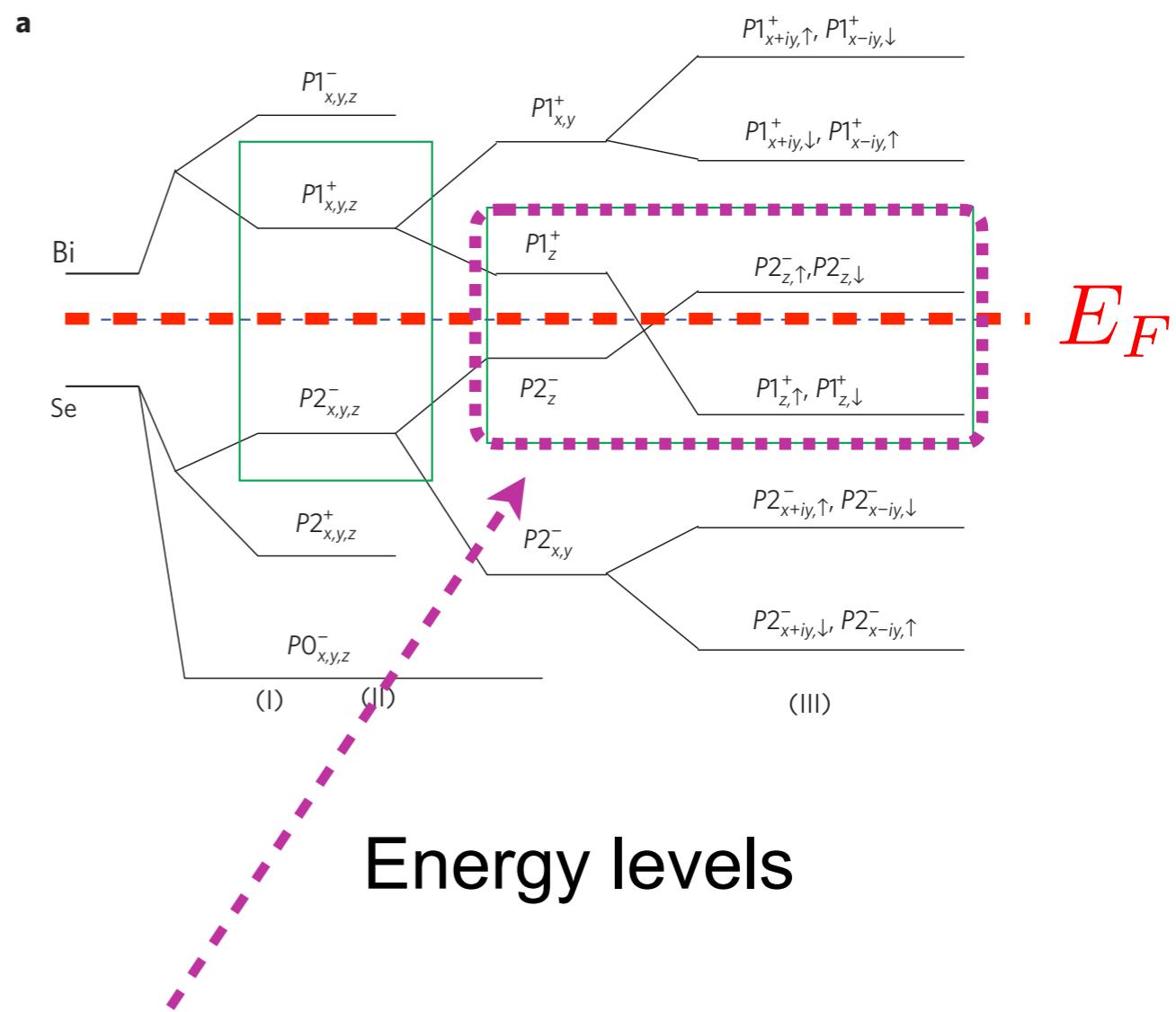
Energy levels

Let's consider 3D TI, Bi_2Se_3

H. Zhang et al. '09

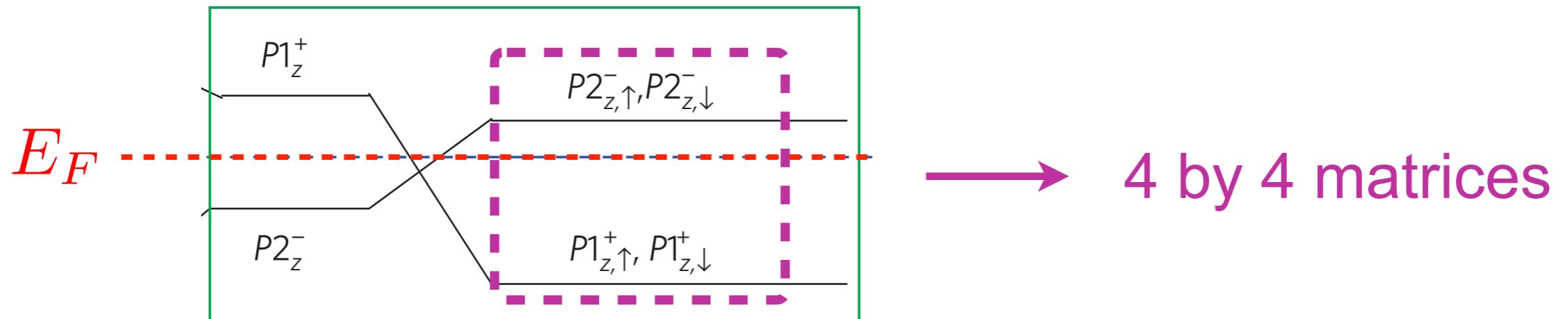


Cristal structure



Energy levels

Band inversion due to strong SOC



$$H_0(\mathbf{k}) = \epsilon_0 \mathbf{1}_{4 \times 4} + \sum_{a=1}^5 d^a \Gamma^a$$

$$(d^1, d^2, d^3, d^4, d^5) = (A_2 \sin k_x, A_2 \sin k_y, A_1 \sin k_z, \mathcal{M}(\mathbf{k}), 0)$$

$$\mathcal{M}(\mathbf{k}) = M - 2B_1 - 4B_2 + 2B_1 \cos k_z + 2B_2 (\cos k_x + \cos k_y)$$

$$\Gamma^1 = \begin{pmatrix} 0 & \sigma^x \\ \sigma^x & 0 \end{pmatrix} \quad \Gamma^2 = \begin{pmatrix} 0 & \sigma^y \\ \sigma^y & 0 \end{pmatrix} \quad \Gamma^3 = \begin{pmatrix} 0 & -i\mathbf{1} \\ -i\mathbf{1} & 0 \end{pmatrix}$$

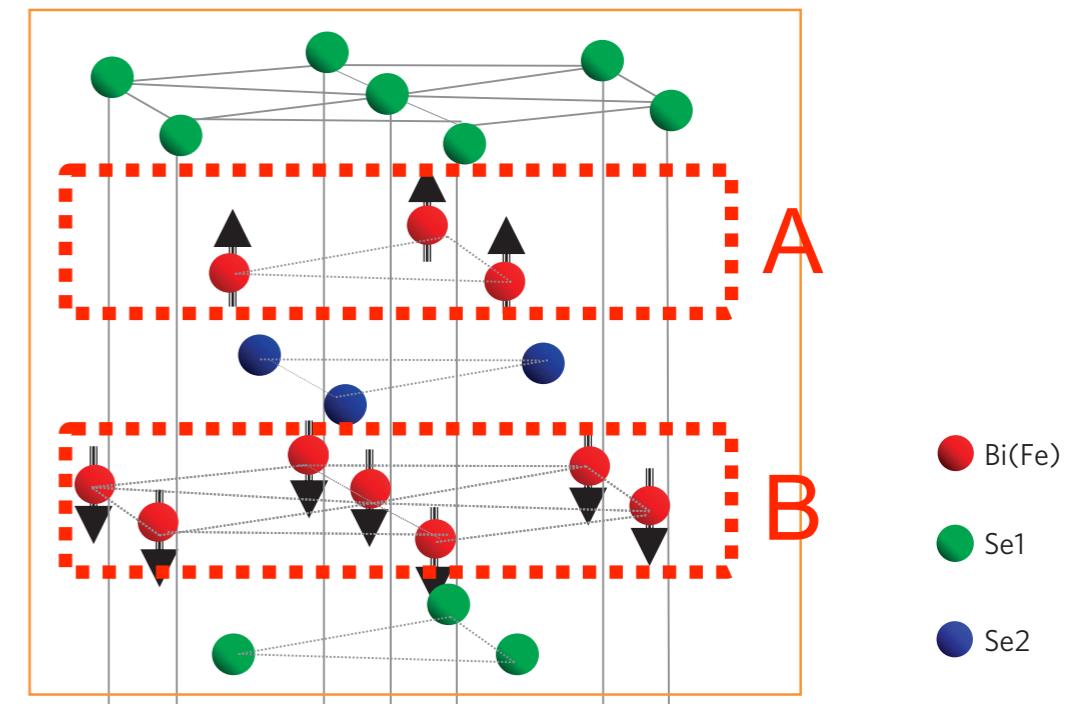
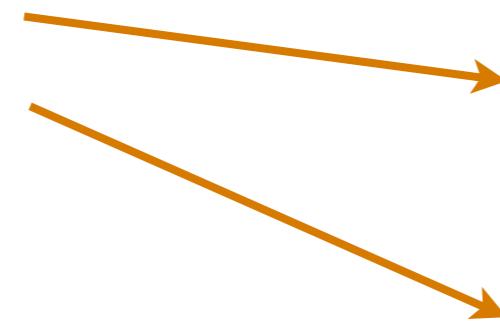
$$\Gamma^4 = \begin{pmatrix} \mathbf{1} & 0 \\ 0 & -\mathbf{1} \end{pmatrix} \quad \Gamma^5 = \begin{pmatrix} 0 & \sigma^z \\ \sigma^z & 0 \end{pmatrix}$$

“Effective Hamiltonian for 3D TI”

In addition we consider *antiferromagnetism (AFM)*

R. Li et al. '10

Suppose electrons at Bi
are AFM order



In addition we consider *antiferromagnetism (AFM)*

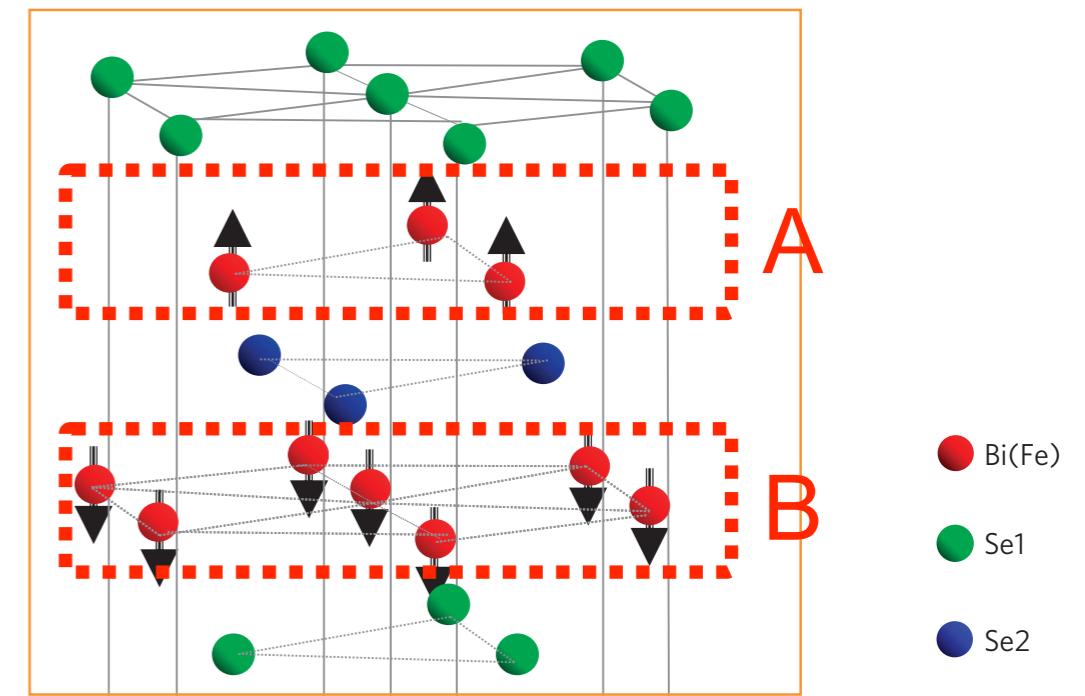
R. Li et al. '10

$$\mathcal{H}_{\text{int}} = \frac{UV}{N} \int d^3x (n_{A\uparrow}n_{A\downarrow} + n_{B\uparrow}n_{B\downarrow})$$

“Hubbard term”

U : parameter to give AFM

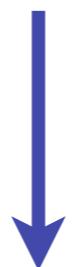
Large U \rightarrow AFM



V : volume
 N : number of site

$$n_{A\sigma} = \psi_{A\sigma}^\dagger \psi_{A\sigma}$$
$$n_{B\sigma} = \psi_{B\sigma}^\dagger \psi_{B\sigma}$$

$$\mathcal{H}_{\text{int}} = \frac{UV}{N} \int d^3x (n_{A\uparrow}n_{A\downarrow} + n_{B\uparrow}n_{B\downarrow})$$



Hubbard-Stratonovich (HS)
transformation

~ Inverse of integrating out a scalar

$$\mathcal{H}_{\text{int}} = \frac{UV}{N} \int d^3x (n_{A\uparrow}n_{A\downarrow} + n_{B\uparrow}n_{B\downarrow})$$



Hubbard-Stratonovich (HS)
transformation

- A dynamical scalar ϕ that gives $\Gamma^5 d_5$ ($d_5 = \phi$)
- Mass term of ϕ

$$\mathcal{H}_{\text{int}} = \frac{UV}{N} \int d^3x (n_{A\uparrow}n_{A\downarrow} + n_{B\uparrow}n_{B\downarrow})$$

Hubbard-Stratonovich (HS) transformation

- A dynamical scalar ϕ that gives $\Gamma^5 d_5$ ($d_5 = \phi$)
 - Mass term of ϕ  missed in Sekine, Nomura '16
Sekine, Nomura '20
Schütte-Engel '21

$$\mathcal{H}_{\text{int}} = \frac{UV}{N} \int d^3x (n_{A\uparrow}n_{A\downarrow} + n_{B\uparrow}n_{B\downarrow})$$



Hubbard-Stratonovich (HS)
transformation

- A dynamical scalar ϕ that gives $\Gamma^5 d_5$ ($d_5 = \phi$)
- Mass term of ϕ
- ϕ relates to the axion field

$$\theta = \frac{1}{4\pi} \int d^3k \frac{2|d| + d^4}{(|d| + d^4)^2 |d|^3} \epsilon^{ijkl} d^i \partial_{k_x} d^j \partial_{k_y} d^k \partial_{k_z} d^l$$

Partition function (TI + AFM)

$$Z = \int \mathcal{D}\psi \mathcal{D}\psi^\dagger \mathcal{D}\phi \ e^{iS+iS_\phi^{\text{mass}}}$$

$$S = \int d^4x \ \psi^\dagger(x) [i\partial_t - H] \psi(x) \qquad \qquad H = H_0 + \delta H$$

$$S_\phi^{\text{mass}} = - \int d^4x \ M_\phi^2 \phi^2$$

$$M_\phi^2 = \int \frac{d^3k}{(2\pi)^3} \frac{2}{U}$$

Partition function (TI + AFM)

$$Z = \int \mathcal{D}\psi \mathcal{D}\psi^\dagger \boxed{\mathcal{D}\phi} e^{iS+iS_\phi^{\text{mass}}}$$

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$$S_\phi^{\text{mass}} = - \int d^4x \ M_\phi^2 \phi^2$$

$\Gamma^5 \phi$

$$H = H_0 + \boxed{\delta H}$$

$$M_\phi^2 = \int \frac{d^3k}{(2\pi)^3} \frac{2}{U}$$

Partition function (TI + AFM)

$$Z = \int \mathcal{D}\psi \mathcal{D}\psi^\dagger \boxed{\mathcal{D}\phi} e^{iS+iS_\phi^{\text{mass}}}$$

$$S = \int d^4x \ \psi^\dagger(x) [i\partial_t - H] \psi(x)$$

$$S_\phi^{\text{mass}} = - \int d^4x \ M_\phi^2 \phi^2$$

$$\Gamma^5 \phi \downarrow \\ H = H_0 + \boxed{\delta H}$$

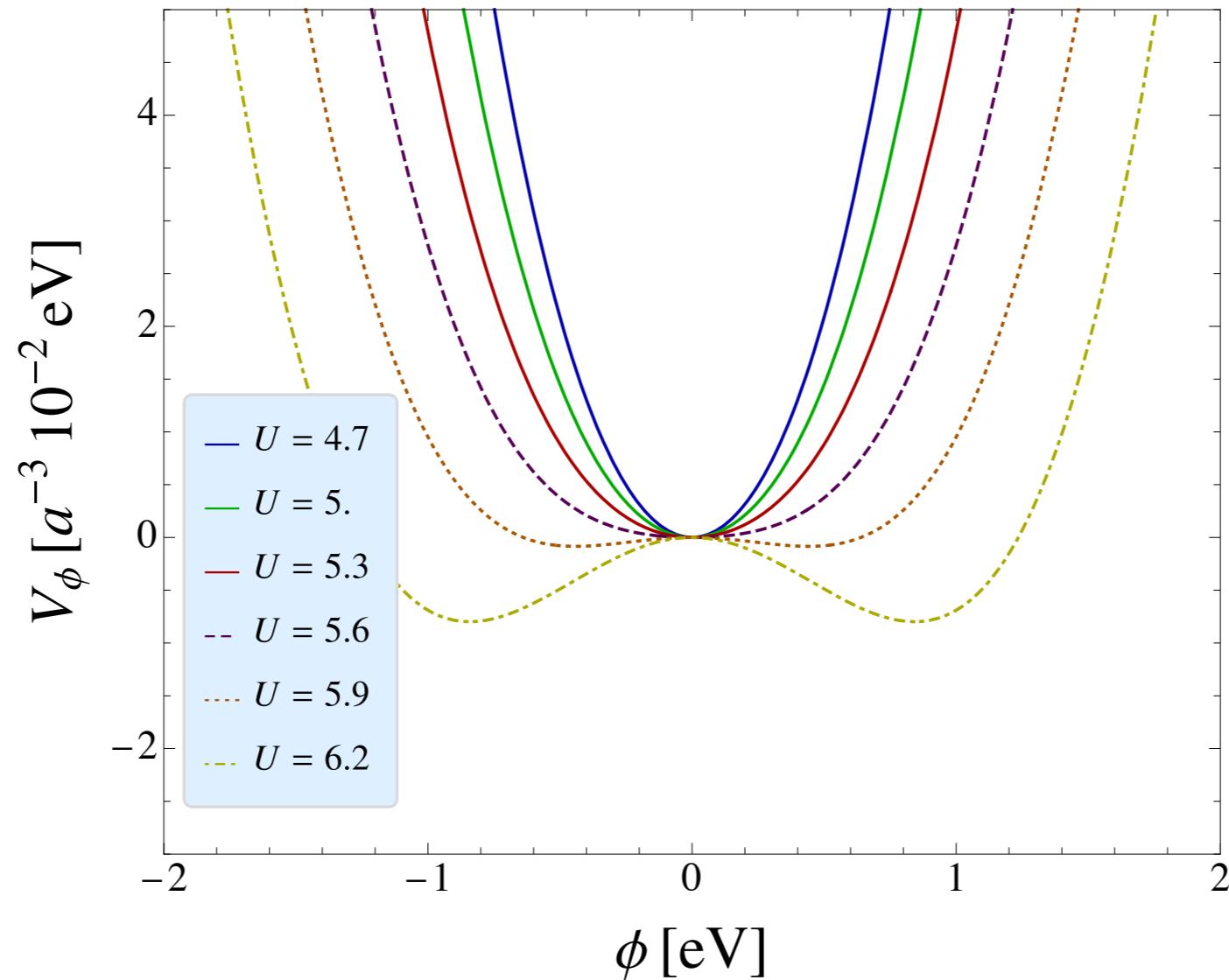
$$M_\phi^2 = \int \frac{d^3k}{(2\pi)^3} \frac{2}{U}$$

Summing over ψ, ψ^\dagger

..... \rightarrow Effective potential for ϕ

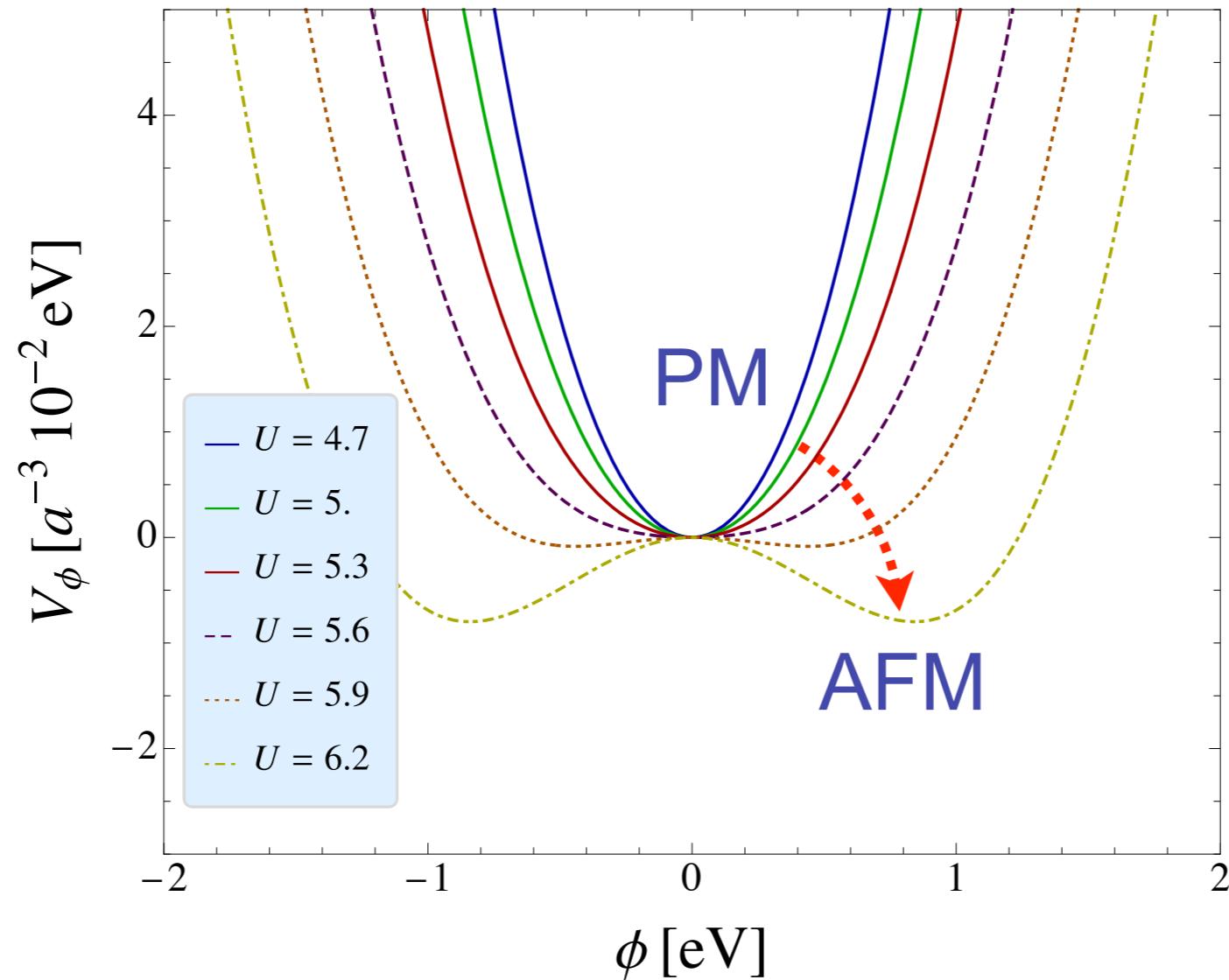
..... \rightarrow Effective potential for θ

$$\theta = \frac{1}{4\pi} \int d^3k \frac{2|d| + d^4}{(|d| + d^4)^2 |d|^3} \epsilon^{ijkl} d^i \partial_{k_x} d^j \partial_{k_y} d^k \partial_{k_z} d^l$$

Effective model for 3D TI, M [eV] = 0.1

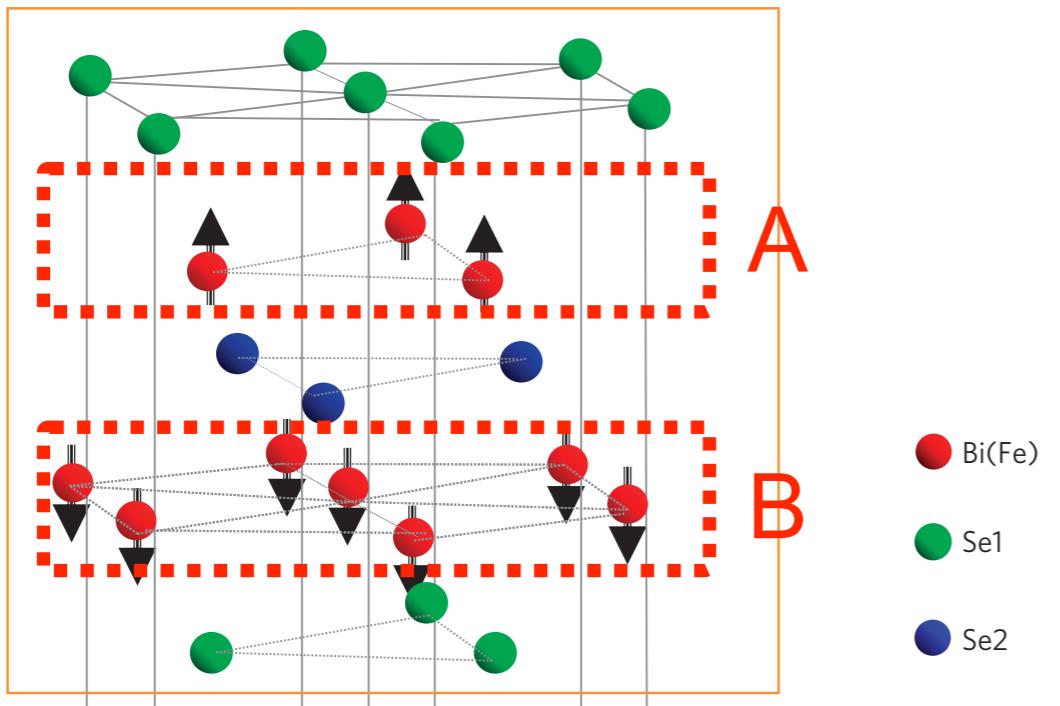
$$A_1 = A_2 = 1$$

$$B_1 = B_2 = -0.5$$

Effective model for 3D TI, M [eV] = 0.1

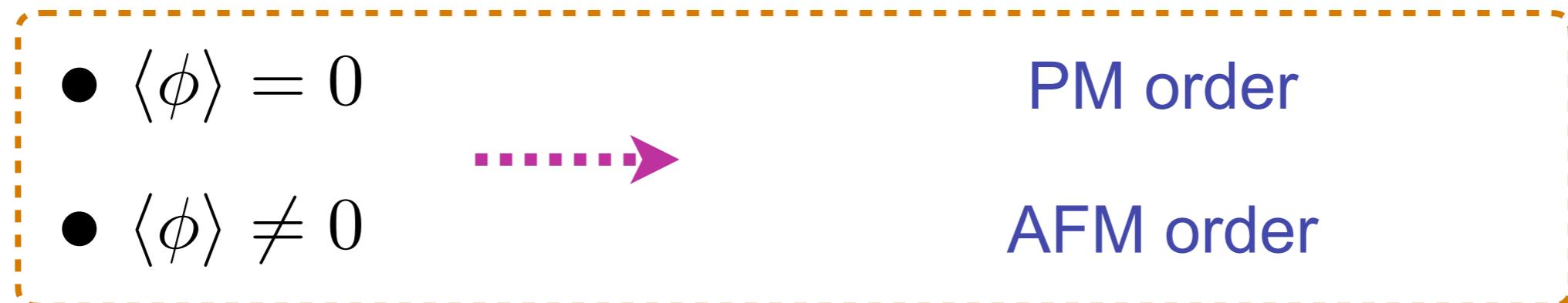
$$A_1 = A_2 = 1$$

$$B_1 = B_2 = -0.5$$



$$\langle \phi \rangle \sim \langle S_A \rangle = -\langle S_B \rangle$$

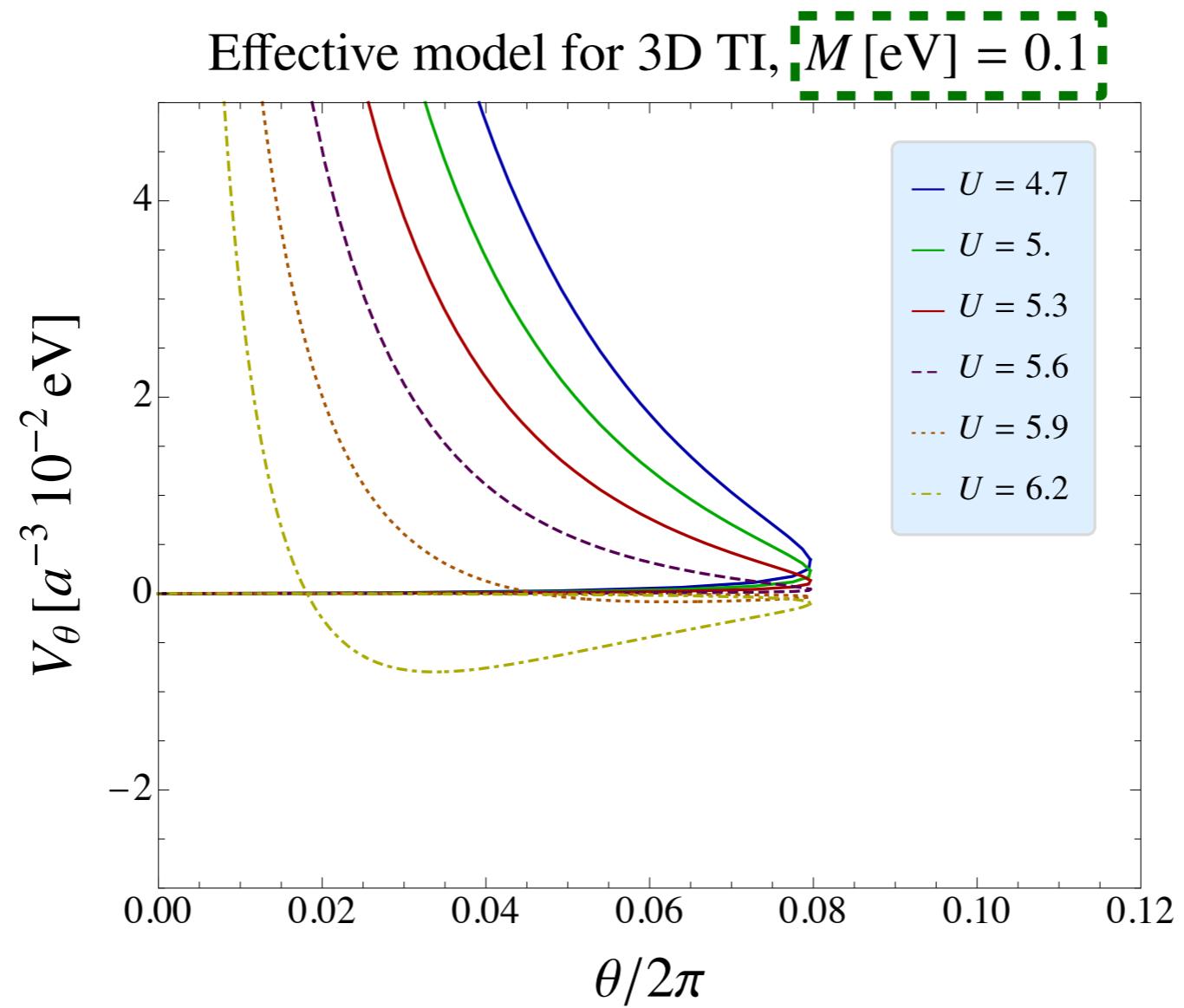
VEV of ϕ is the order parameter of AFM



PM (paramagnetic)

Effective potential in terms of θ

KI '21



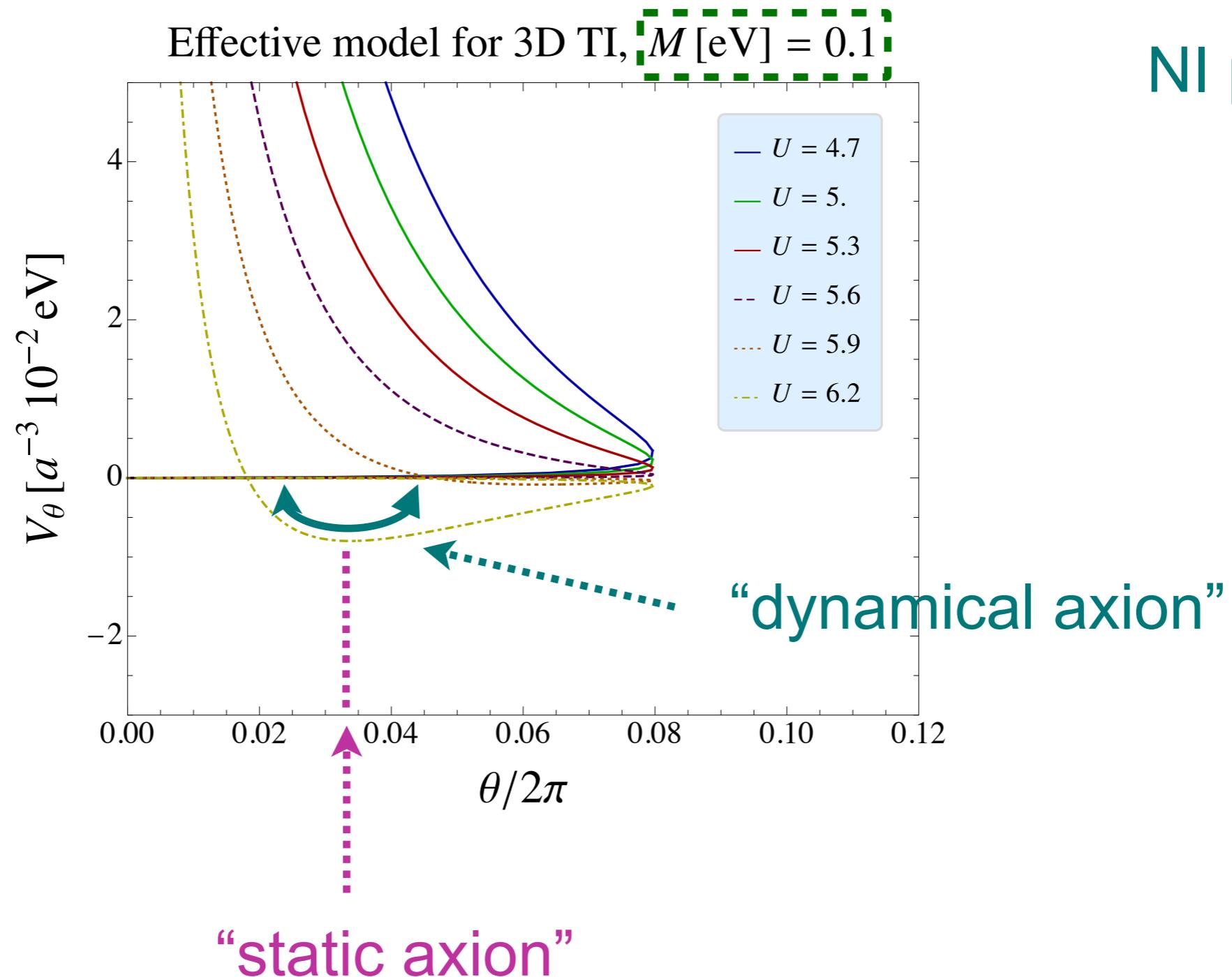
NI phase

Potential minimum:

- $\theta = 0$ (PM)
- $\theta \neq 0$ (AFM)

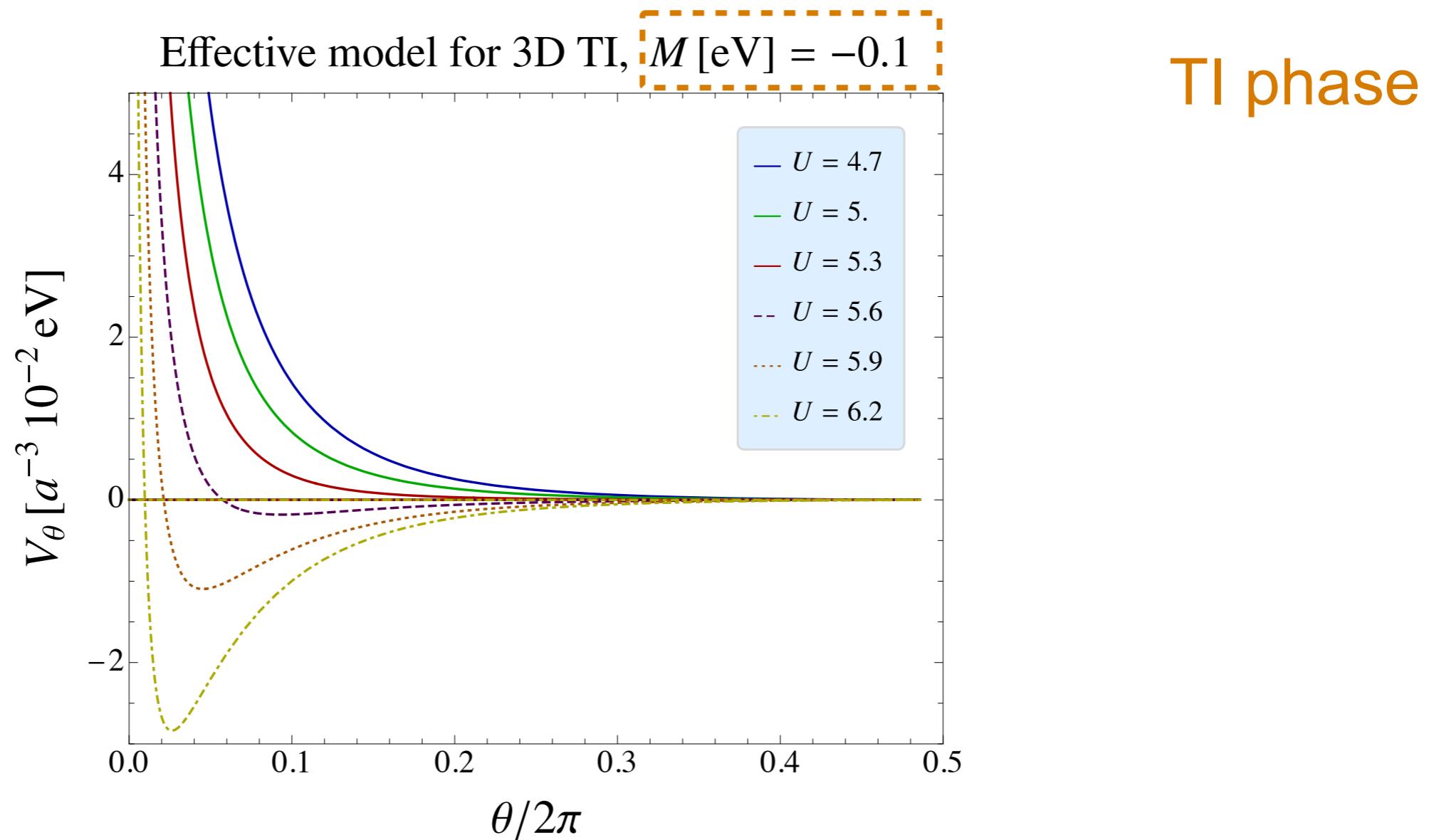
Effective potential in terms of θ

KI '21



Effective potential in terms of θ

KI '21

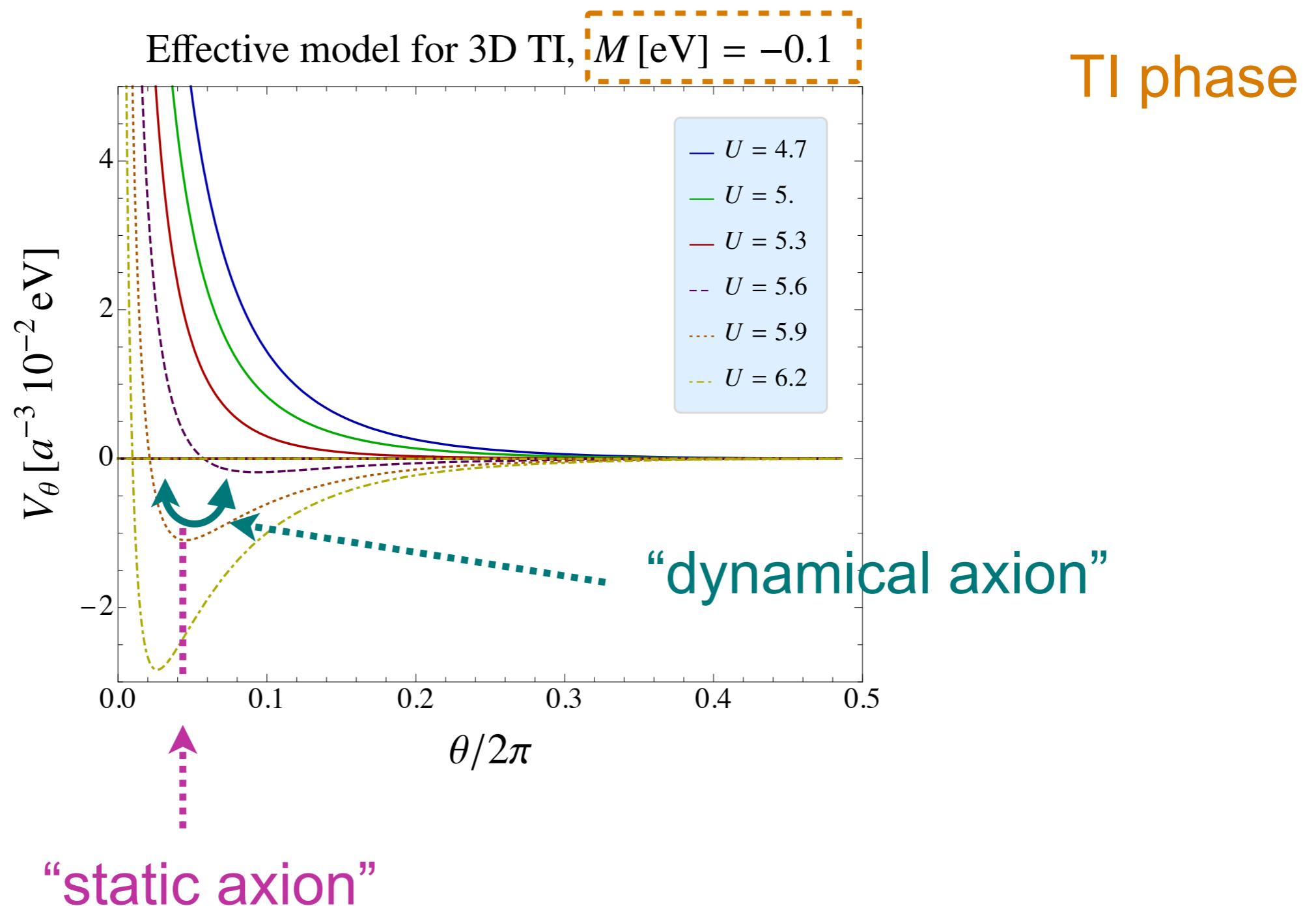


Potential minimum:

- $\theta = \pi$ (PM)
- $\theta \neq 0$ (AFM)

Effective potential in terms of θ

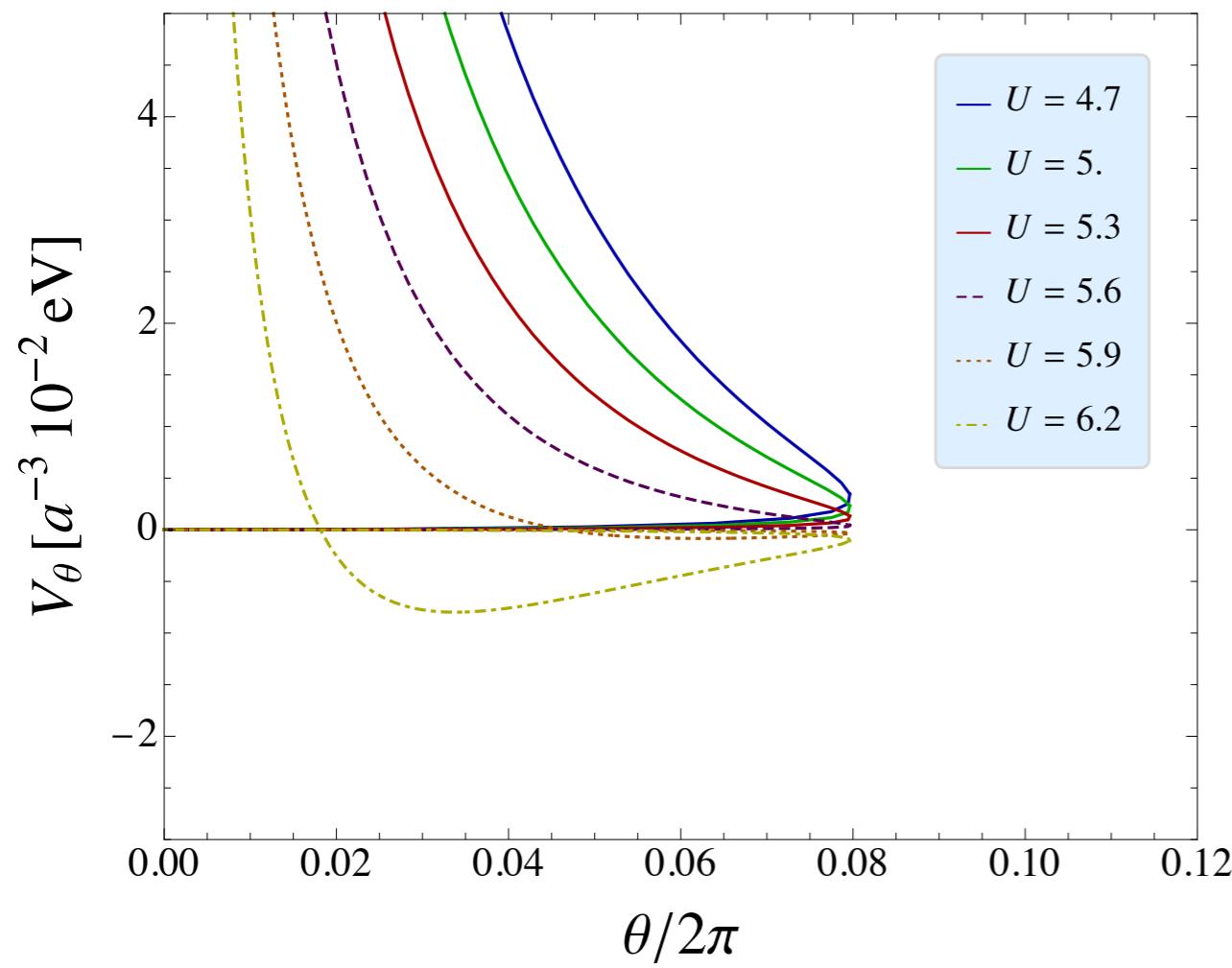
KI '21



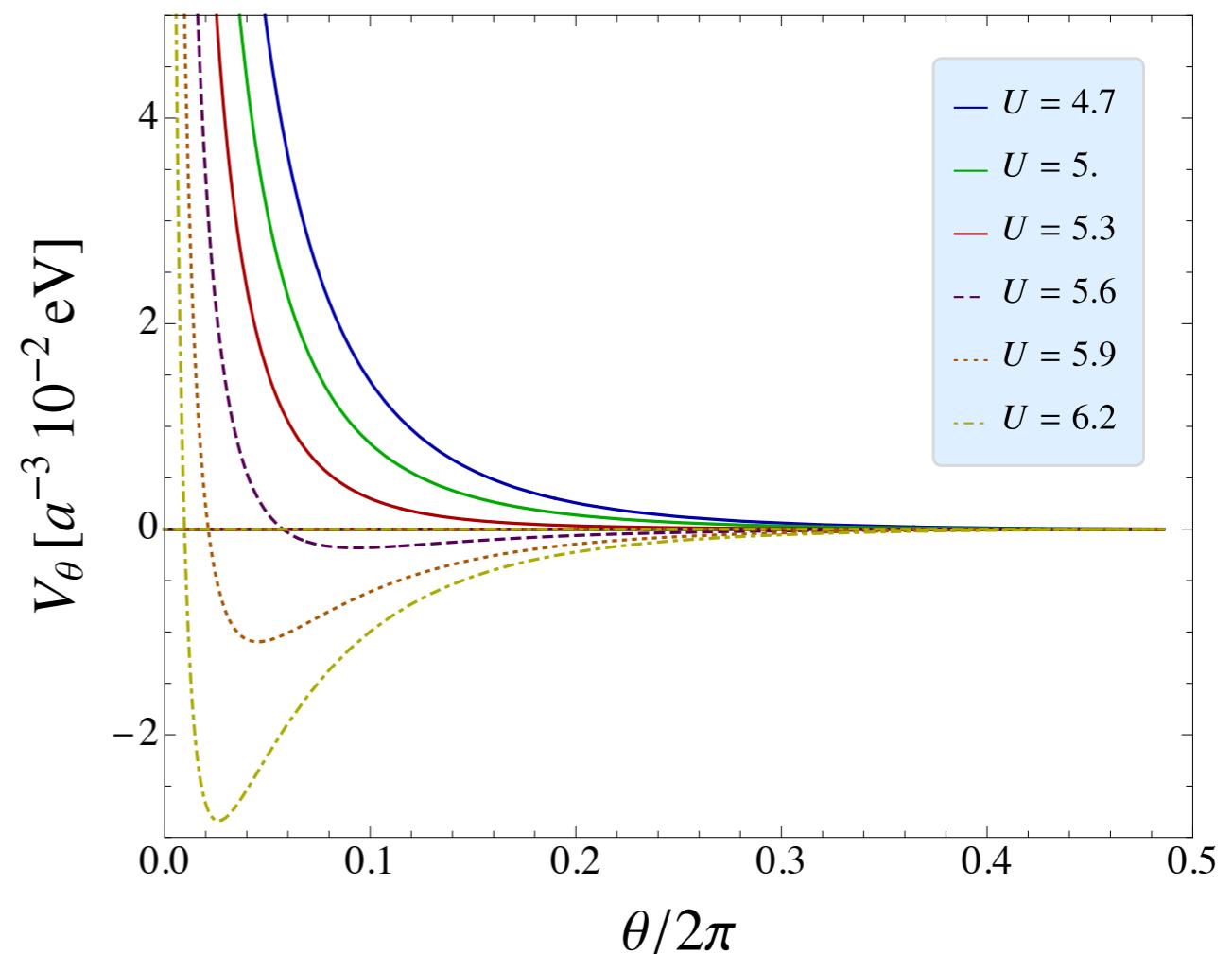
Axion in antiferromagnetic insulators

KI '21

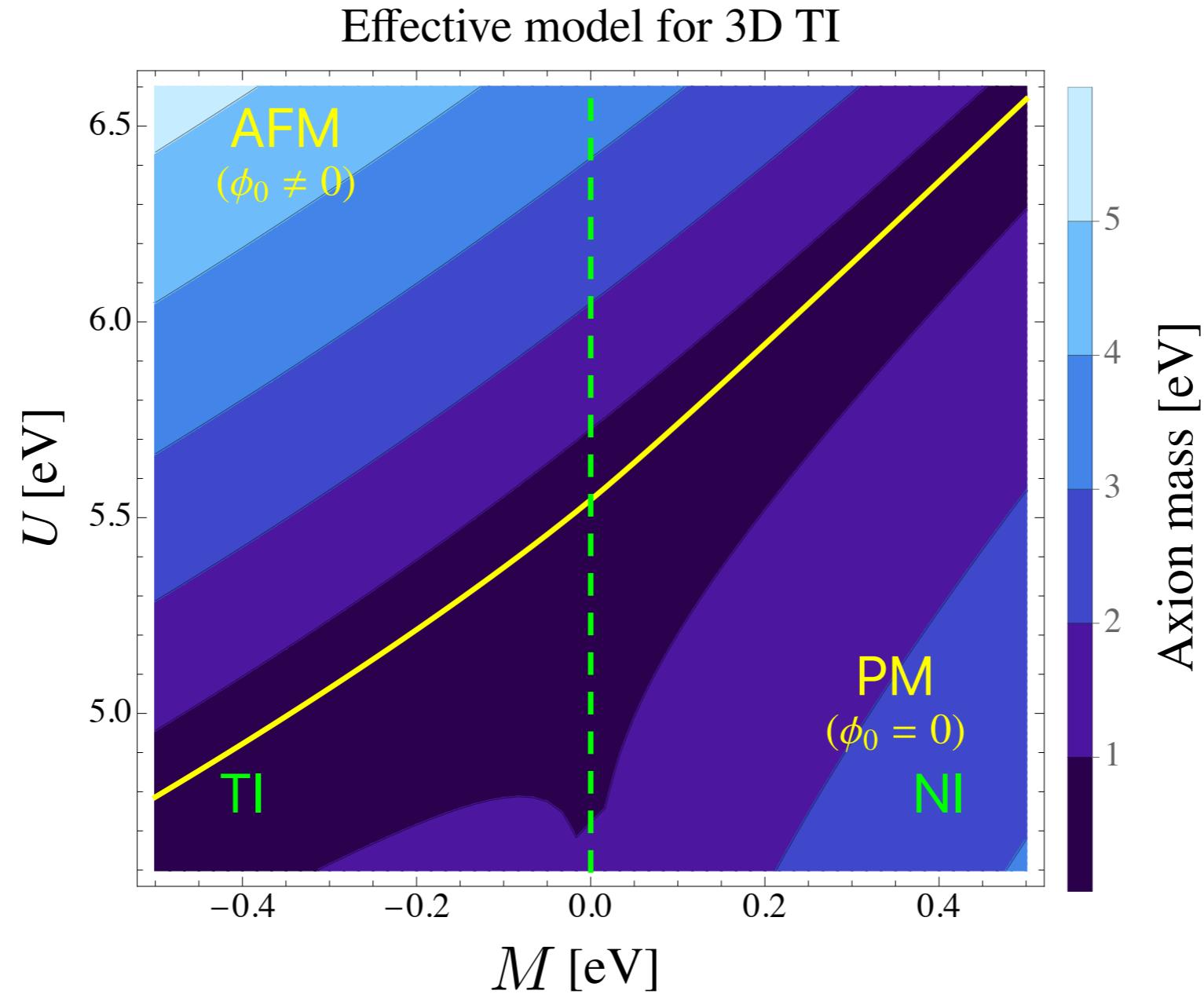
Effective model for 3D TI, M [eV] = 0.1



Effective model for 3D TI, M [eV] = -0.1



Dynamical axion exists in both TI and NI phases



Axion mass is $\lesssim \mathcal{O}(\text{eV})$

Dynamical axion is predicted in topological magnetic insulators

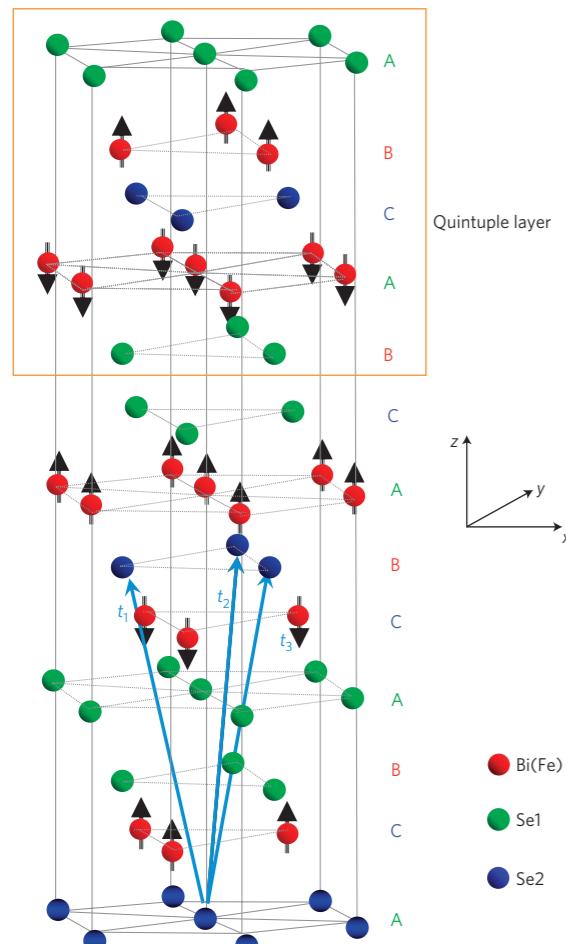
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nature
physics

Dynamical axion field in topological magnetic insulators

Rundong Li¹, Jing Wang^{1,2}, Xiao-Liang Qi¹ and Shou-Cheng Zhang^{1*}



Bi_2Se_3

$$\begin{aligned} \mathcal{S}_{\text{tot}} &= \mathcal{S}_{\text{Maxwell}} + \mathcal{S}_{\text{topo}} + \mathcal{S}_{\text{axion}} \\ &= \frac{1}{8\pi} \int d^3x dt \left(\epsilon E^2 - \frac{1}{\mu} B^2 \right) + \boxed{\frac{\alpha}{4\pi^2} \int d^3x dt (\theta_0 + \delta\theta) E \cdot B} \\ &\quad + g^2 J \int d^3x dt [(\partial_t \delta\theta)^2 - (\nu_i \partial_i \delta\theta)^2 - m^2 \delta\theta^2] \end{aligned} \quad (4)$$

Axion mass $\sim \mathcal{O}(\text{meV})$

?

The thing would be ...

R. Li et al. '10

- $\langle \phi \rangle (= m_5) = 1 \text{ meV}$ is taken
(i.e., $\langle \phi \rangle$ is considered to be a free parameter)
- AFM order is assumed

The thing would be ...

R. Li et al. '10

- $\langle \phi \rangle (= m_5) = 1 \text{ meV}$ is taken
(i.e., $\langle \phi \rangle$ is considered to be a free parameter)

$$\longrightarrow \text{Axion mass} \sim \mathcal{O}(\text{meV}) \quad (\because m_a^2 \propto m_5^2)$$

But this is naively difficult since

- AFM order is assumed $m_5 \sim U \sim \text{eV}$ (in AFM order)

The thing would be ...

R. Li et al. '10

- $\langle \phi \rangle (= m_5) = 1 \text{ meV}$ is taken
(i.e., $\langle \phi \rangle$ is considered to be a free parameter)
→ Axion mass $\sim \mathcal{O}(\text{meV})$ ($\because m_a^2 \propto m_5^2$)
- AFM order is assumed

The thing would be ...

R. Li et al. '10

- $\langle \phi \rangle (= m_5) = 1 \text{ meV}$ is taken

(i.e., $\langle \phi \rangle$ is considered to be a free parameter)

→ Axion mass $\sim \mathcal{O}(\text{meV})$ ($\because m_a^2 \propto m_5^2$)

- AFM order is assumed

No AFM in TI in the first place

→ Fe-doped Bi_2Se_3 is considered

The thing would be ...

R. Li et al. '10

- $\langle \phi \rangle (= m_5) = 1 \text{ meV}$ is taken
(i.e., $\langle \phi \rangle$ is considered to be a free parameter)

→ Axion mass $\sim \mathcal{O}(\text{meV})$ ($\because m_a^2 \propto m_5^2$)

- AFM order is assumed

No AFM in TI in the first place

→ Fe-doped Bi_2Se_3 is considered
“likely to be AFM”
(by first-principles calculation)

J.M. Zhang et al. '13

→ It looks unlikely to be realized

The thing would be ...

R. Li et al. '10

- $\langle \phi \rangle (= m_5) = 1 \text{ meV}$ is taken
(i.e., $\langle \phi \rangle$ is considered to be a free parameter)
 - Axion mass $\sim \mathcal{O}(\text{meV})$ ($\because m_a^2 \propto m_5^2$)
 - Consistent determination of $\langle \phi \rangle$ is crucial for axion mass

- AFM order is assumed

No AFM in TI in the first place

- Fe-doped Bi_2Se_3 is considered

J.M. Zhang et al. '13

4. Conclusions

We have formulated static and dynamical axions in AFM TI consistently by using path integral

- Dynamical axion appears both in TI and NI
- Axion mass is $\lesssim \mathcal{O}(\text{eV})$
- Material search is crucial for the future axion search

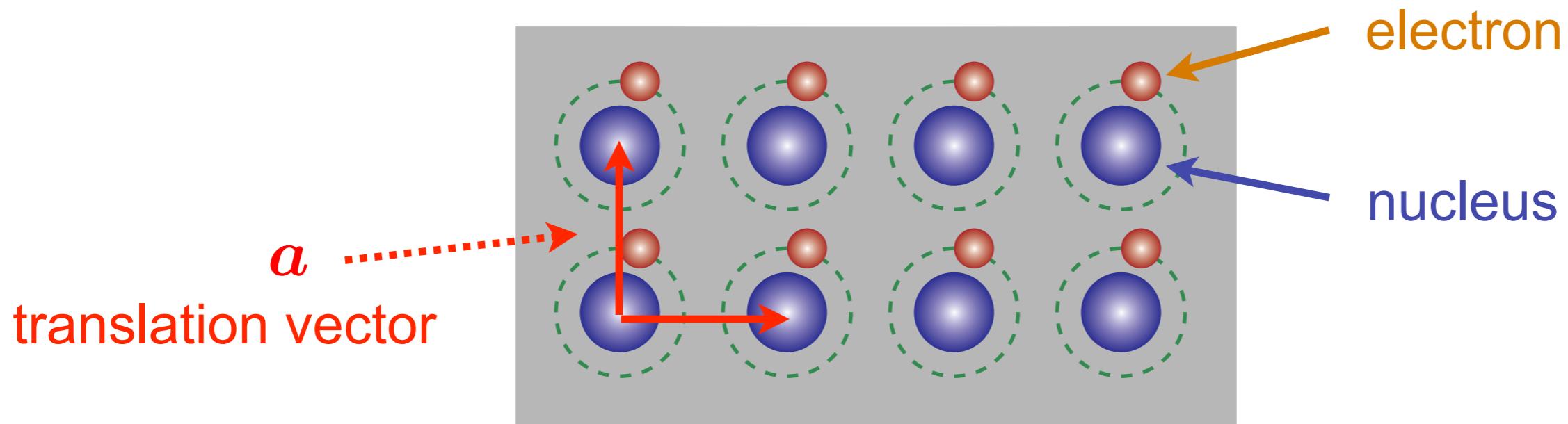
Discussion

- How do we describe axion in $\text{Mn}_2\text{Bi}_2\text{Te}_5$?
- What about axion in NI ?
- Dynamical axion in ferromagnetic state or other magnetic states?

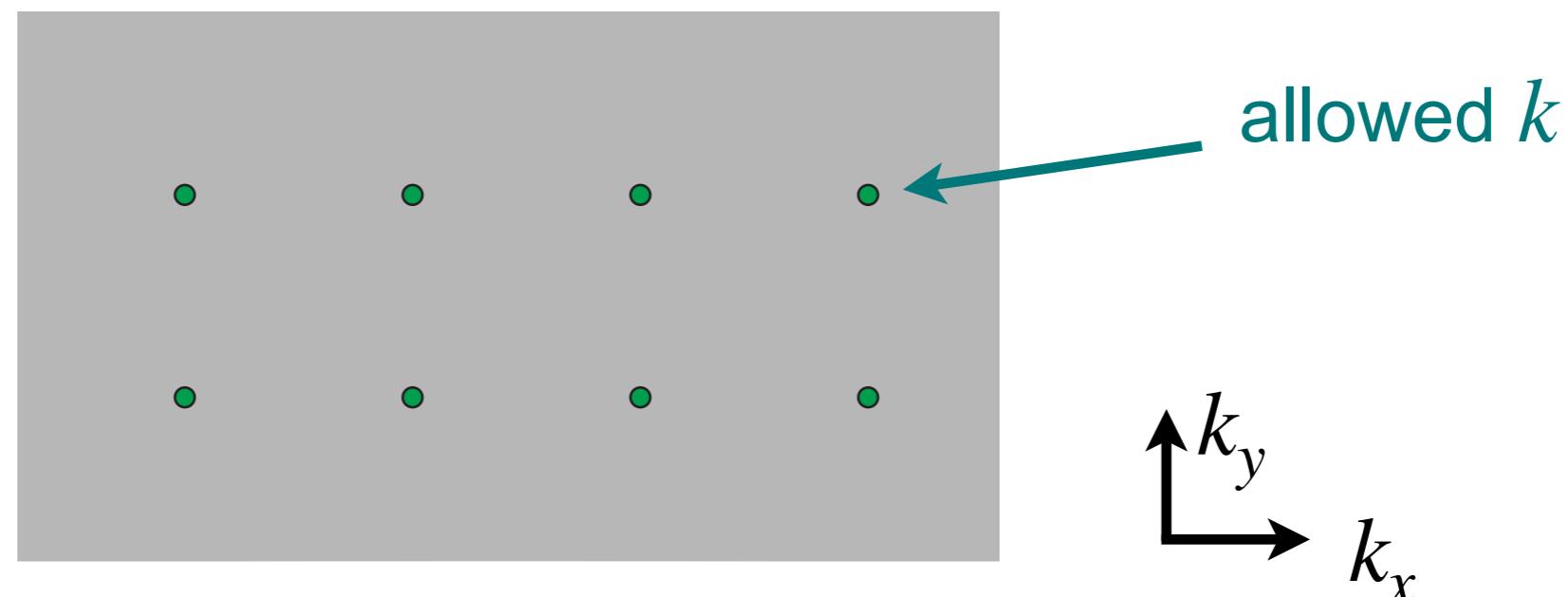
Backups

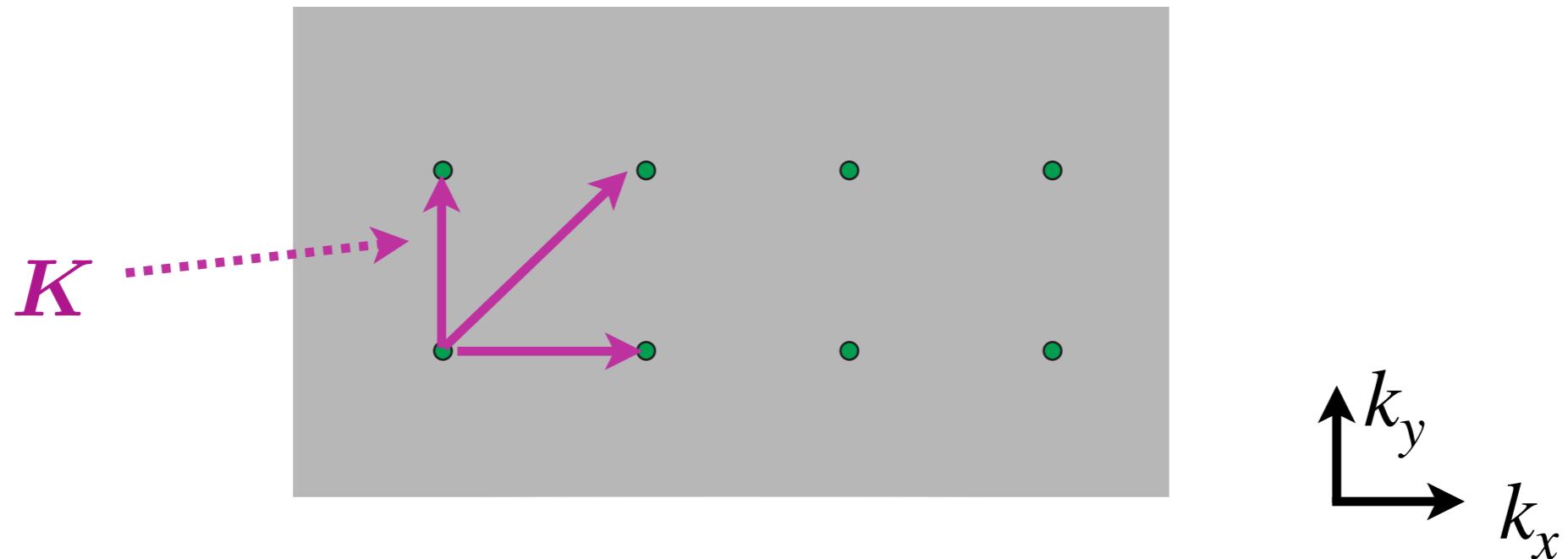
Basics

- Wavefunction of electrons is periodic (due to the crystal structure of the material)



- Consequently there is periodicity in the wavenumber space





- Periodicity $x \rightarrow x + a$ corresponds to $\mathbf{k} \rightarrow \mathbf{k} + \mathbf{K}$
(\mathbf{K} : reciprocal lattice vector)
- It is enough to consider region, $|\mathbf{k}| \lesssim |\mathbf{K}/2|$ (1st Brillouin zone)
- The wavefunction of the electrons is given by
$$\psi(\mathbf{x}) = u_{\mathbf{k}}(\mathbf{x})e^{i\mathbf{k}\cdot\mathbf{x}}$$
 where $u_{\mathbf{k}}(\mathbf{x} + \mathbf{a}) = u_{\mathbf{k}}(\mathbf{x})$
Bloch function (state) (Bloch's theorem)

Thouless, Kohmoto, Nightingale, den Nijs '82

Hall conductivity:

$$\sigma_{xy} \equiv \langle j_x \rangle / E_y = \nu \frac{e^2}{h}$$

TKNN formula

$$\nu \equiv \sum_n \int_{\text{BZ}} \frac{d^2k}{2\pi} [\nabla_{\mathbf{k}} \times \mathbf{a}_n(\mathbf{k})]_z$$
$$\mathbf{a}_n(\mathbf{k}) \equiv -i \langle u_{n\mathbf{k}} | \frac{\partial}{\partial \mathbf{k}} | u_{n\mathbf{k}} \rangle$$

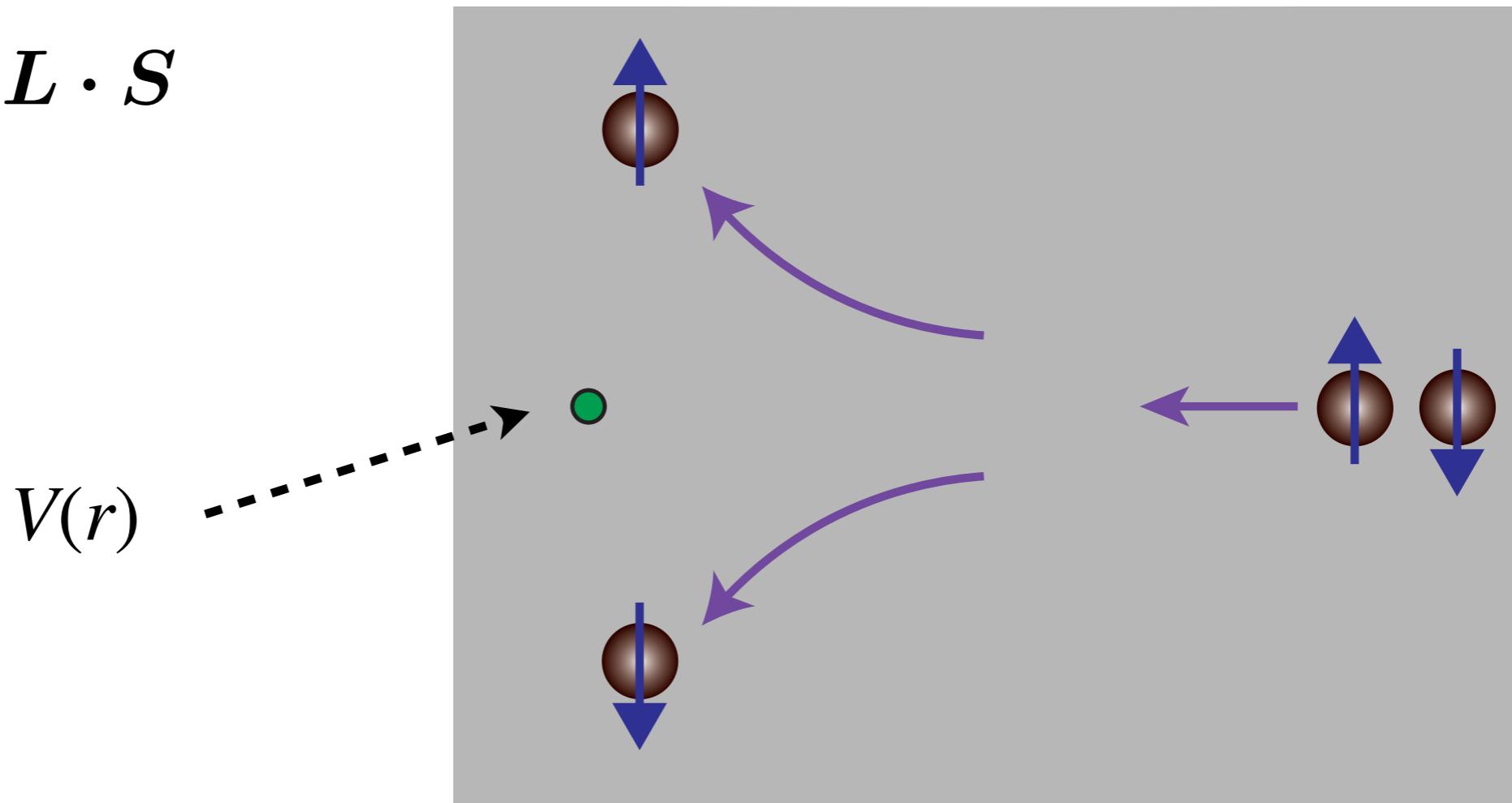
$|u_{n\mathbf{k}}\rangle$: Bloch state
 n : label of band

→ ν is given by (half-) integer
“(Integer) QH effect”

Spin-orbit coupling (SOC)

e.g.,

$$H_{\text{SO}} = V(r) \mathbf{L} \cdot \mathbf{S}$$



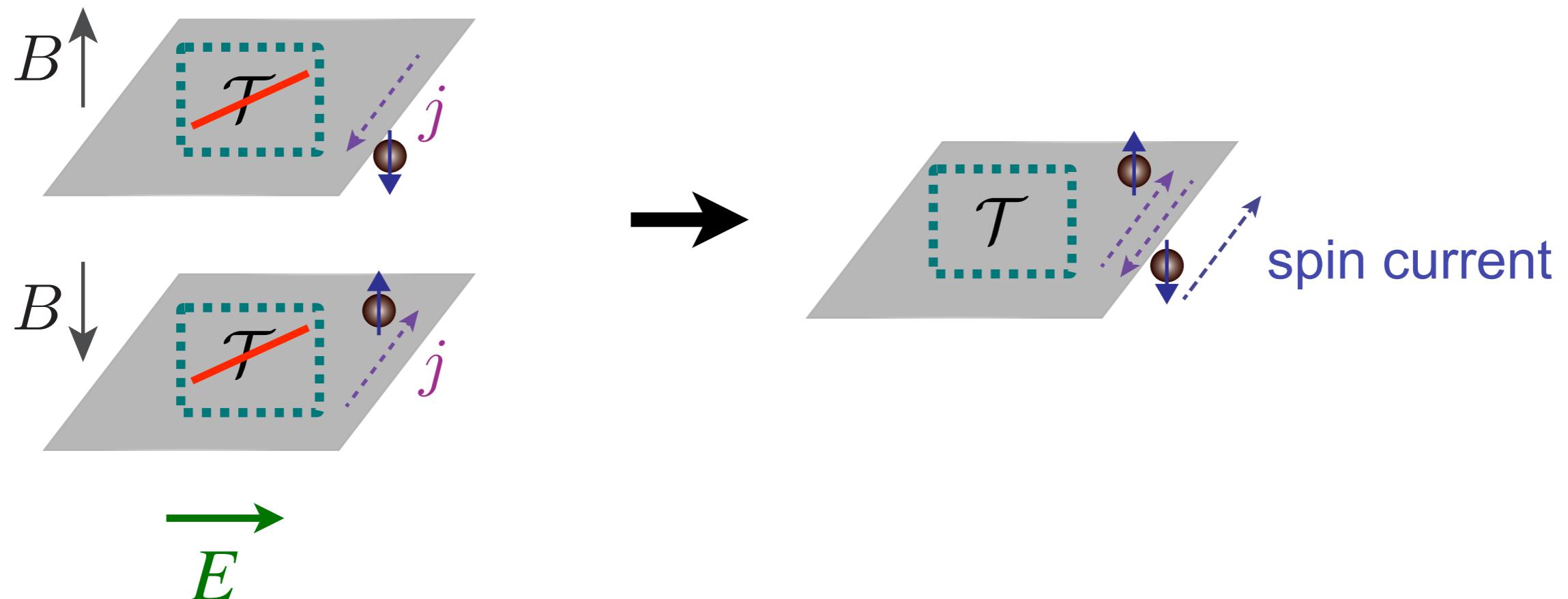
Electrons with spin up or down are scattered off to the opposite directions

Keywords for topological insulators

- Time reversal invariance (\mathcal{T})
- Strong spin-orbit coupling (SOC)

Keywords for topological insulators

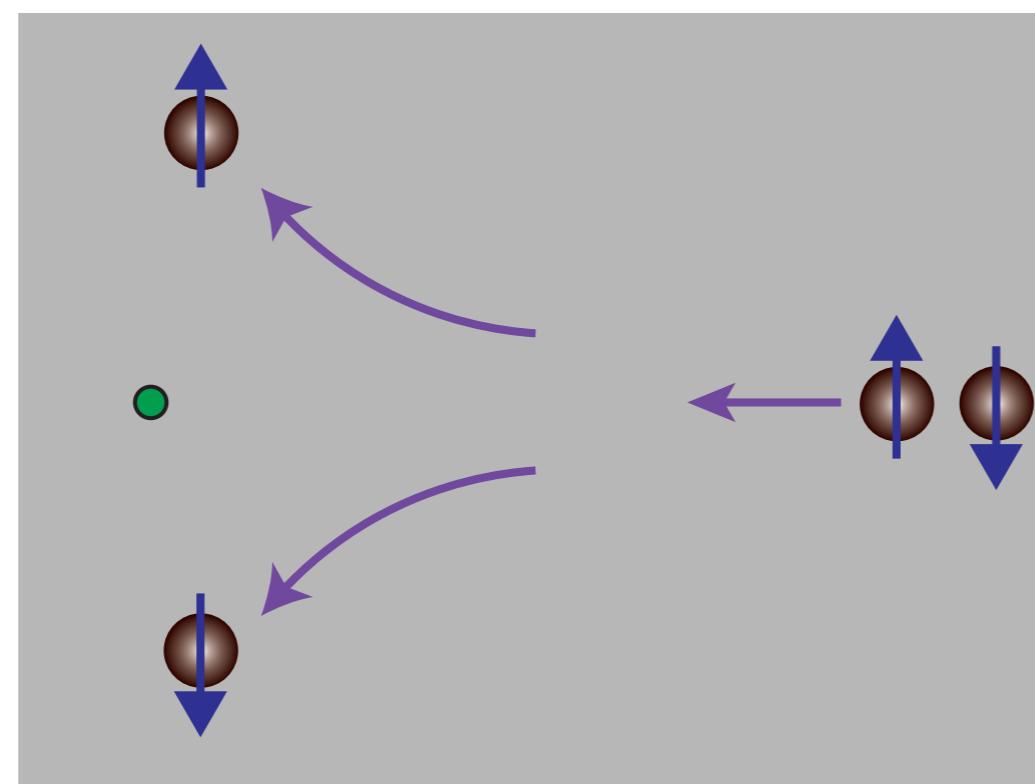
- Time reversal invariance (\mathcal{T})
- Strong spin-orbit coupling (SOC)



B breaks \mathcal{T} but the combination of B and $-B$ keeps \mathcal{T}

Keywords for topological insulators

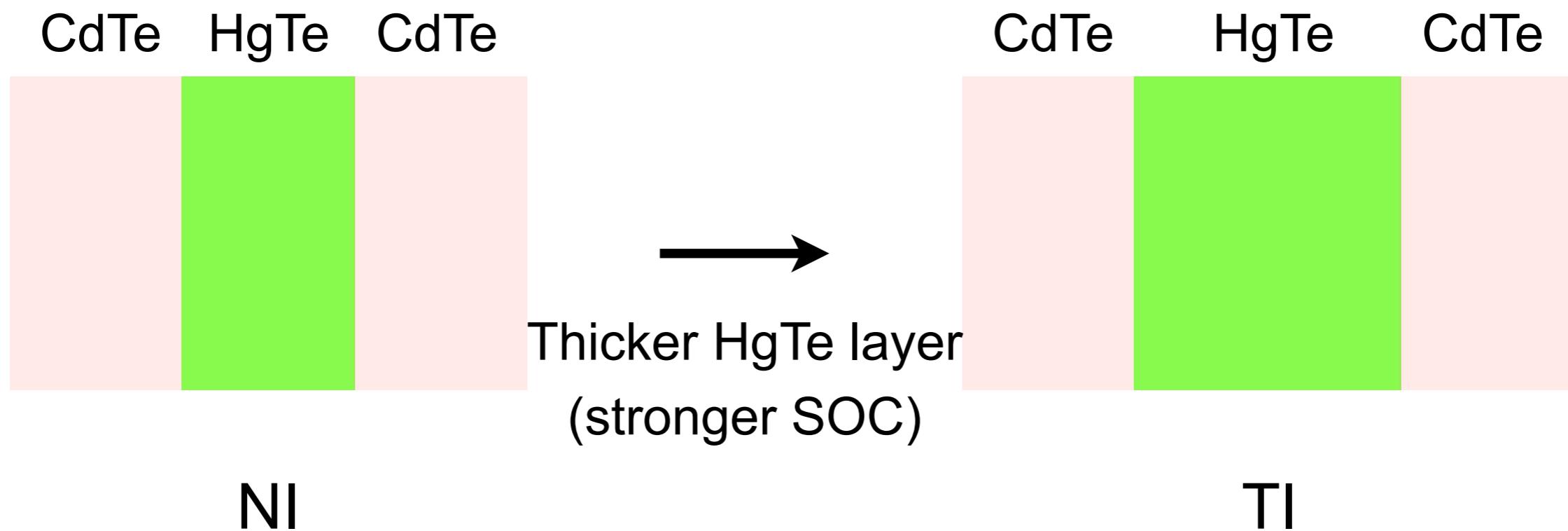
- Time reversal invariance (\mathcal{T})
- Strong spin-orbit coupling (SOC)



Strong SOC is crucial for the realization

Example of 2D TI: HgTe/(Hg_xCd)

König et al. '07



Band inversion happens in the energy band of HgTe

Magnetoelectric (ME) effect

predicted by Landau&Lifshitz
discovered by Dzyaloshinskii '60

- Electric field (E) induces magnetization M
- Magnetic field (B) induces electric polarization P

$$M_j = \alpha_{ij} E_i$$

$$P_i = \alpha_{ij} B_j$$



$$F = -\frac{1}{\mu_0 c} \int d^3x \ \alpha_{ij} E_i B_j$$

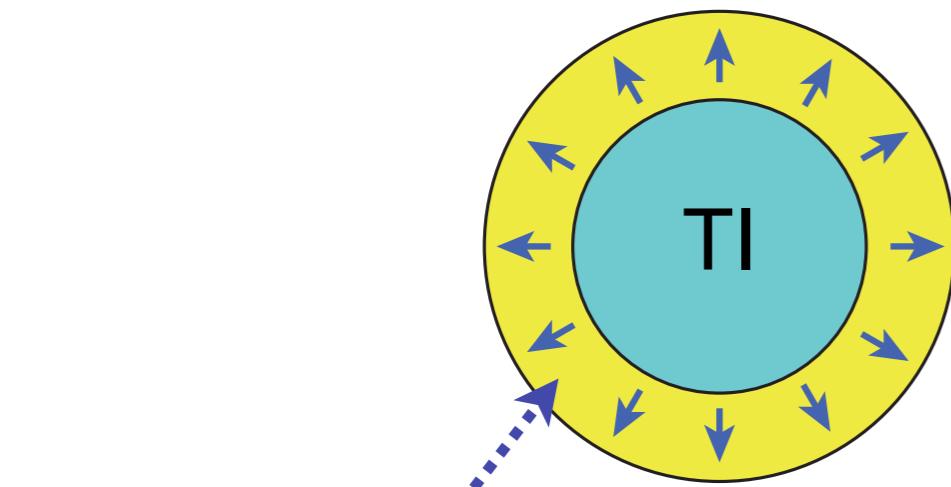
$$M_i = -\frac{1}{V} \left. \frac{\partial F}{\partial E_i} \right|_{B=0}$$

$$P_i = -\frac{1}{V} \left. \frac{\partial F}{\partial B_i} \right|_{E=0}$$

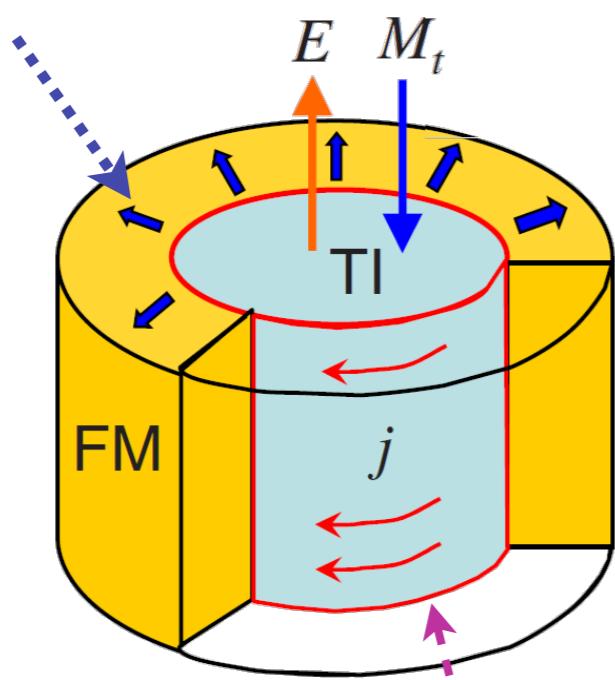
α_{ij} : constant

3D TI cylinder coated with magnetization directing outside

Qi, Hughes, Zhang '08



magnetization



Hall current

Half-integer AQH current



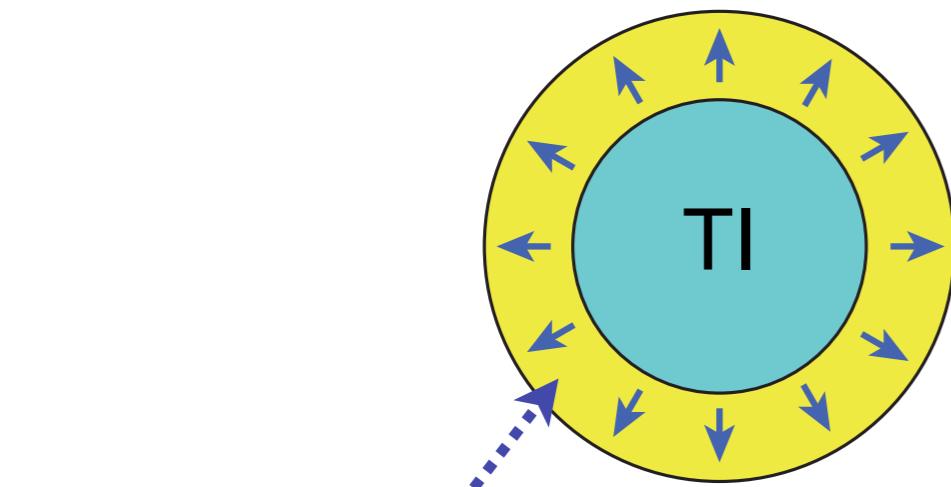
The current induces magnetization
in z direction

$$M = \pm \frac{\alpha}{\mu_0 c} E$$

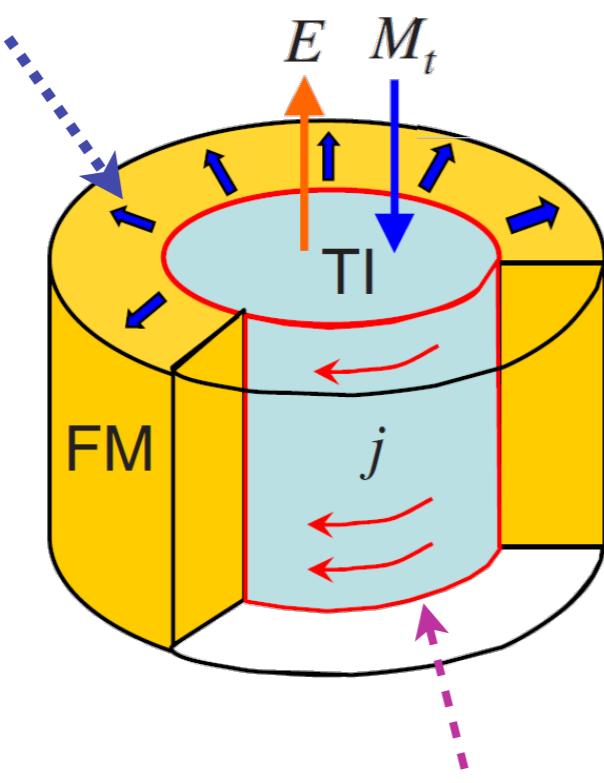
α : fine-structure constant

3D TI cylinder coated with magnetization directing outside

Qi, Hughes, Zhang '08



magnetization



Hall current

Half-integer AQH current



The current induces magnetization
in z direction

$$M = \pm \frac{\alpha}{\mu_0 c} E$$

The coefficient is given by
fine-structure constant

α : fine-structure constant

d). Magnetoelectric effect

This ME effect can be understood from the following free energy:

$$F_\theta = -\frac{1}{\mu_0} \int d^3x \frac{\alpha}{c\pi} \theta \mathbf{E} \cdot \mathbf{B} \quad \text{with} \quad \theta = \pm\pi$$

d). Magnetoelectric effect

This ME effect can be understood from the following free energy:

$$F_\theta = -\frac{1}{\mu_0} \int d^3x \left[\frac{\alpha}{c\pi} \theta \mathbf{E} \cdot \mathbf{B} \right] \quad \text{with} \quad \theta = \pm\pi$$

→ $-\frac{\alpha}{4\pi} \theta F_{\mu\nu} \tilde{F}^{\mu\nu}$

$\theta = \pm \pi$ is called static axion

($\theta = 0$ in NI)

Effective potential for ϕ

KI '21

$$V_\phi = \boxed{-2 \int \frac{d^3 k}{(2\pi)^3} (\sqrt{|d_0|^2 + \phi^2} - |d_0|)} + \boxed{M_\phi^2 \phi^2}$$

Negative potential



The mass term stabilizes the potential

$$\boxed{|d_0|^2 = \sum_{a=1}^4 |d^a|^2}$$
$$\boxed{M_\phi^2 = \int \frac{d^3 k}{(2\pi)^3} \frac{2}{U}}$$

Derivation as chiral anomaly

$$H(\boldsymbol{k}) = \sum_{a=1}^5 d^a(\boldsymbol{k}) \Gamma^a$$

$$(d^1, d^2, d^3, d^4, d^5) = (A_2 \sin k_x, A_2 \sin k_y, A_1 \sin k_z, \mathcal{M}(\boldsymbol{k}), \phi)$$

$$\mathcal{M}(\boldsymbol{k}) = M - 2B_1 - 4B_2 + 2B_1 \cos k_z + 2B_2 (\cos k_x + \cos k_y)$$

Derivation as chiral anomaly

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$$\mathcal{M}(\mathbf{k}) = M - 2B_1 - 4B_2 + 2B_1 \cos k_z + 2B_2 (\cos k_x + \cos k_y)$$



- expand around $\mathbf{k} = 0$
- redefine \mathbf{k}

$$H(\mathbf{k}) = k_x \Gamma^1 + k_y \Gamma^2 + k_y \Gamma^3 + M \Gamma^4 + \phi \Gamma^5$$

“Dirac model”

$$H(\mathbf{k}) = k_x \Gamma^1 + k_y \Gamma^2 + k_y \Gamma^3 + M \Gamma^4 + \phi \Gamma^5$$



Unitary transformation of the basis

$$\tilde{U} H(\mathbf{k}) \tilde{U}^\dagger = \beta(\gamma \cdot \mathbf{k} + M + \phi \gamma_5)$$

→ $S = \int d^4x \bar{\psi} [i\gamma^\mu (\partial_\mu - ieA_\mu) - M - i\phi\gamma_5] \psi$

$\Gamma^5 \phi$ reduces to $i\gamma^5 \phi$

$i\gamma^5\phi$ term can be rotated away, which gives rise to θ term:

$$S_\Theta = -\frac{\alpha}{4\pi} \int d^4x \Theta F_{\mu\nu} \tilde{F}^{\mu\nu}$$

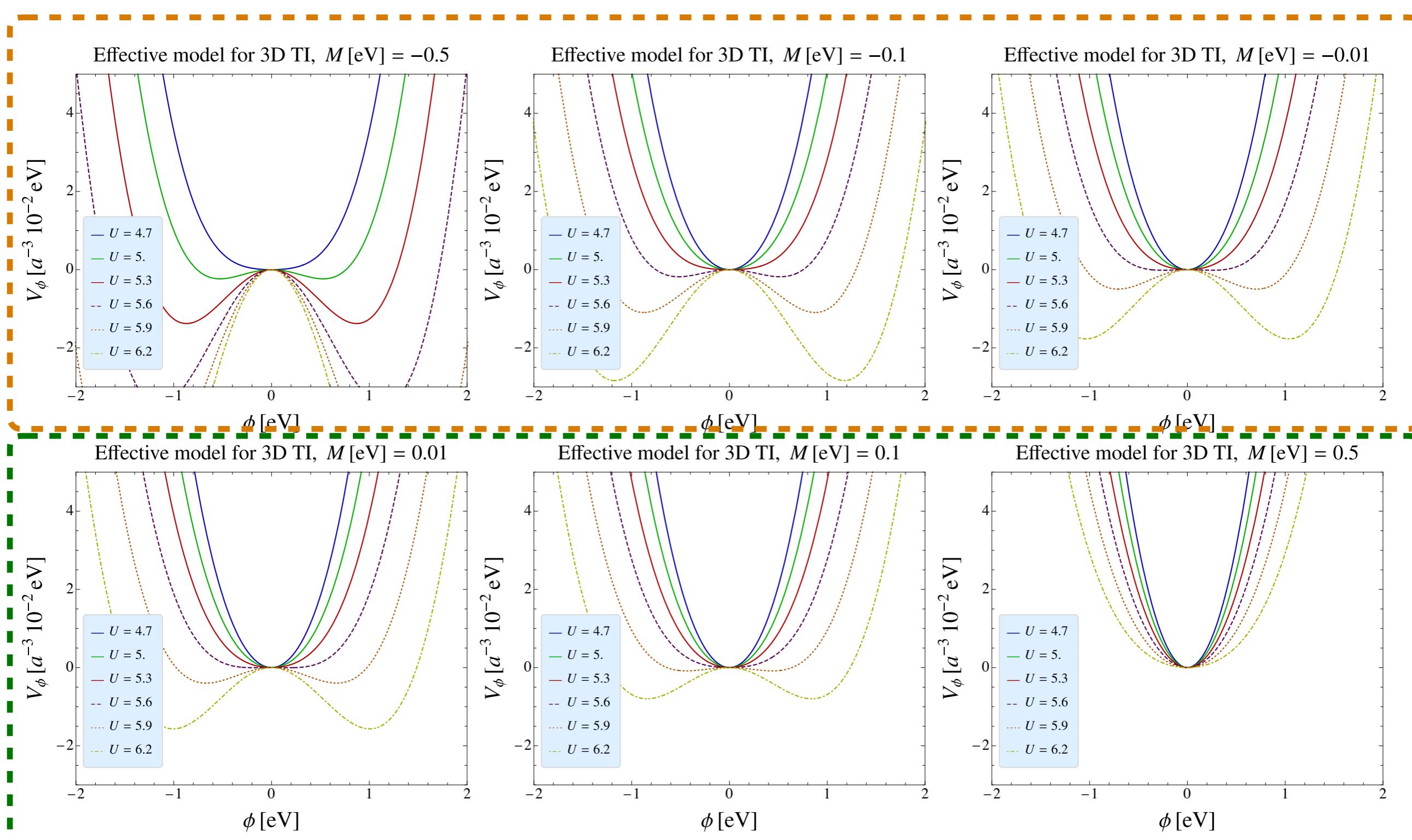
$$\Theta = \frac{\pi}{2} [1 - \text{sgn}(M)] \text{sgn}(\phi) + \tan^{-1} \frac{\phi}{M}$$

it is consistent with

$$\theta = \frac{1}{4\pi} \int d^3k \frac{2|d| + d^4}{(|d| + d^4)^2 |d|^3} \epsilon^{ijkl} d^i \partial_{k_x} d^j \partial_{k_y} d^k \partial_{k_z} d^l$$

M dependence

TI

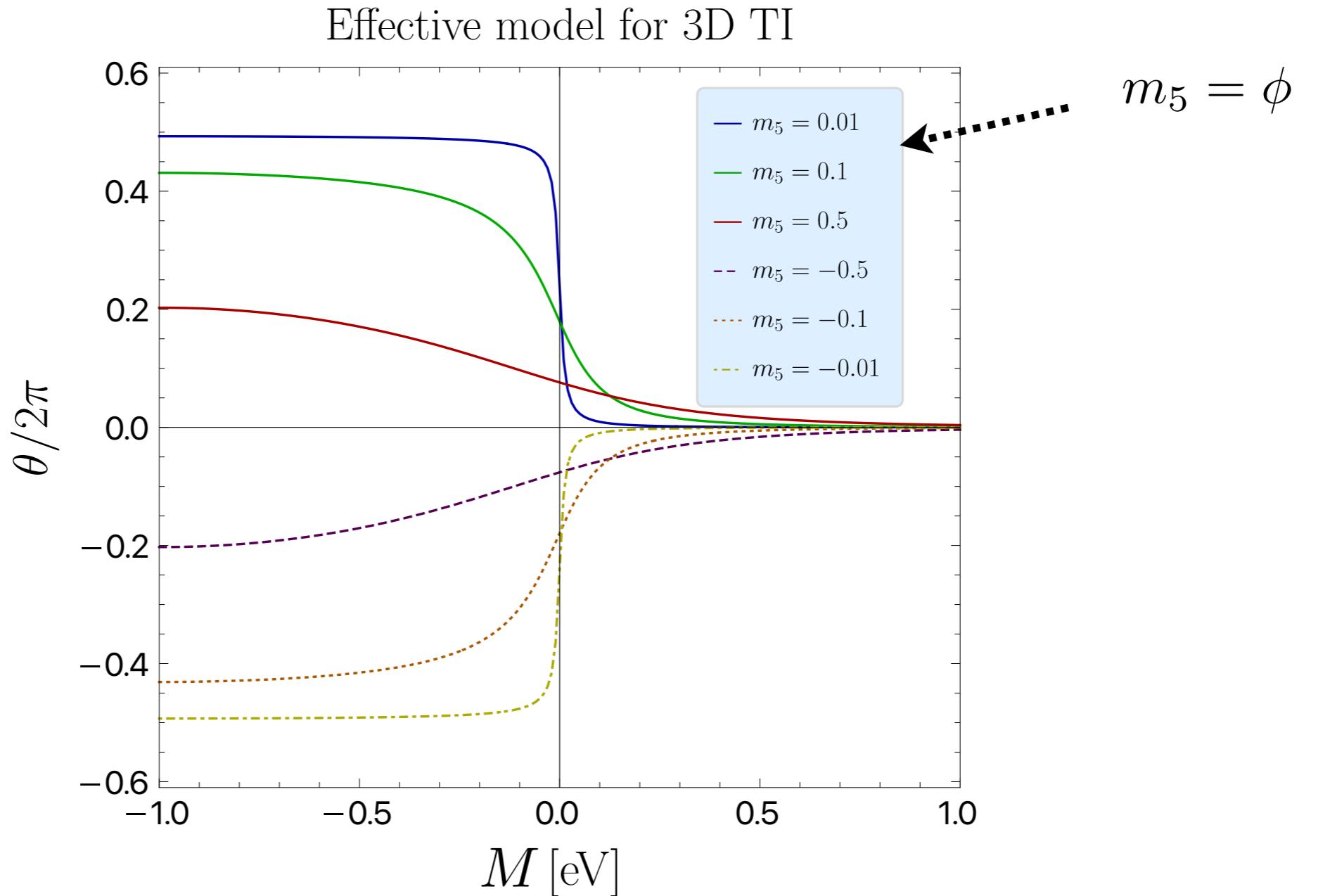


The difference between TI and NI is not clear

NI

θ as function of M

KI '21



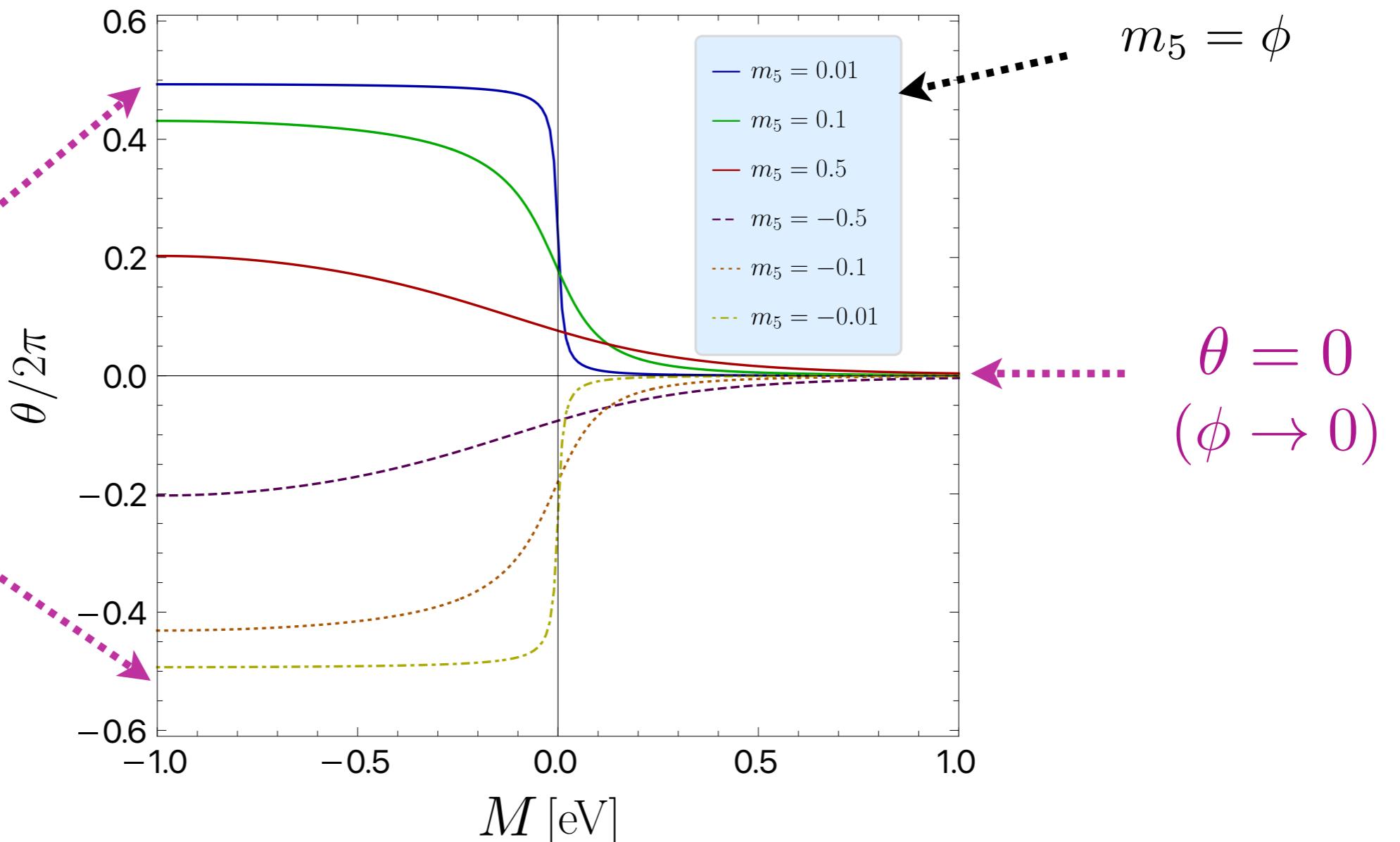
calculation for Dirac
model is done by
Zhang '19

θ as function of M

KI '21

Effective model for 3D TI

$\theta = \pm\pi$
 $(\phi \rightarrow 0)$



$m_5 = \phi$

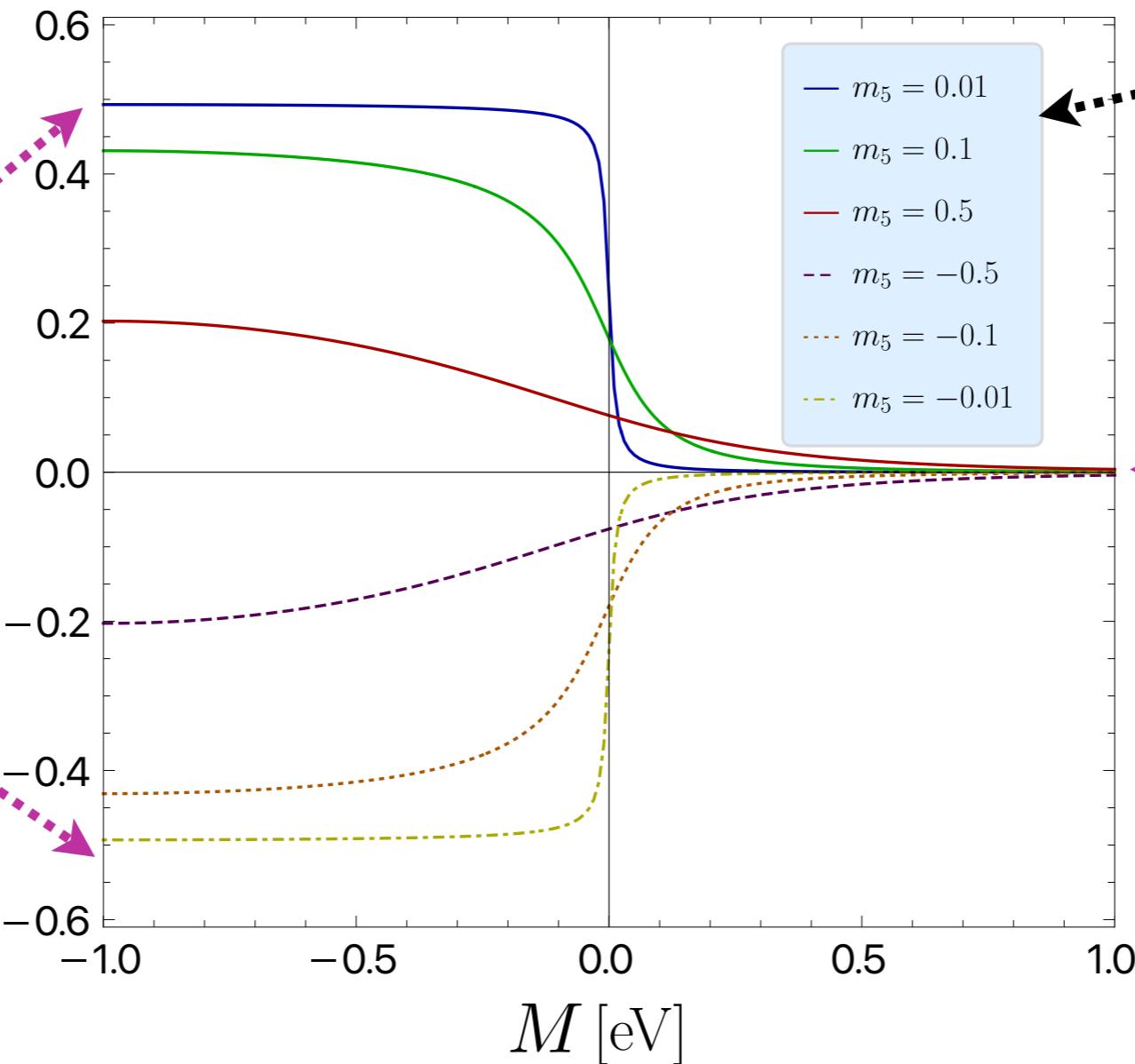
θ as function of M

KI '21

Effective model for 3D TI

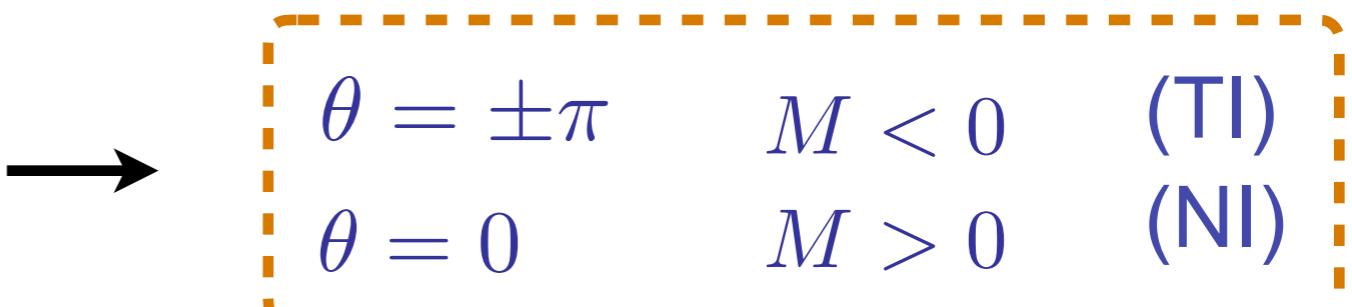
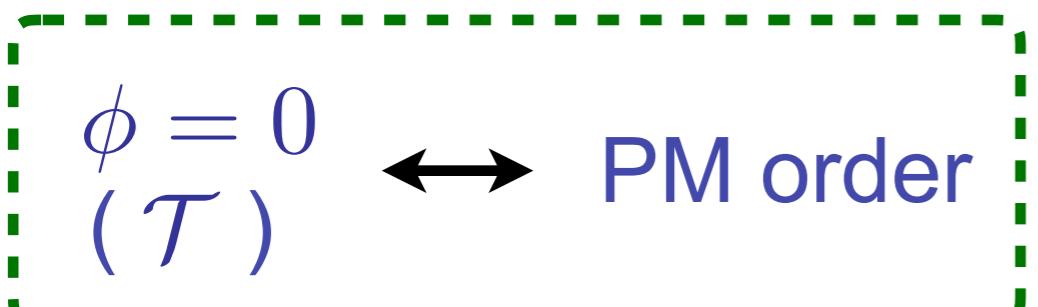
$\theta = \pm\pi$
 $(\phi \rightarrow 0)$

$\theta/2\pi$



$m_5 = \phi$

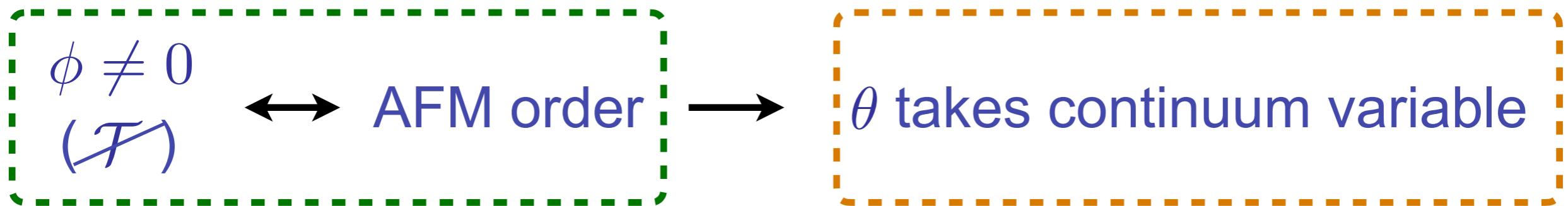
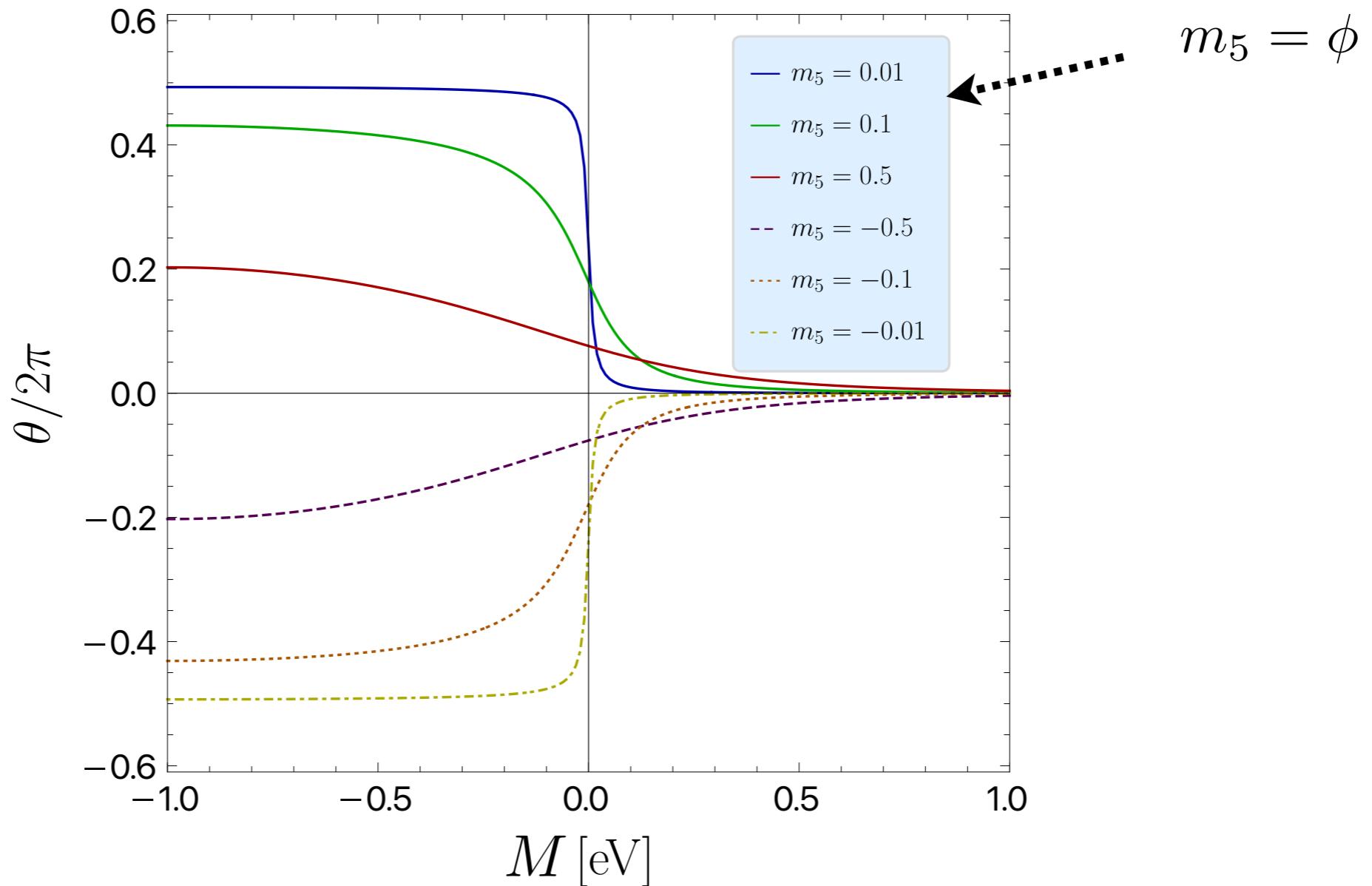
$\theta = 0$
 $(\phi \rightarrow 0)$



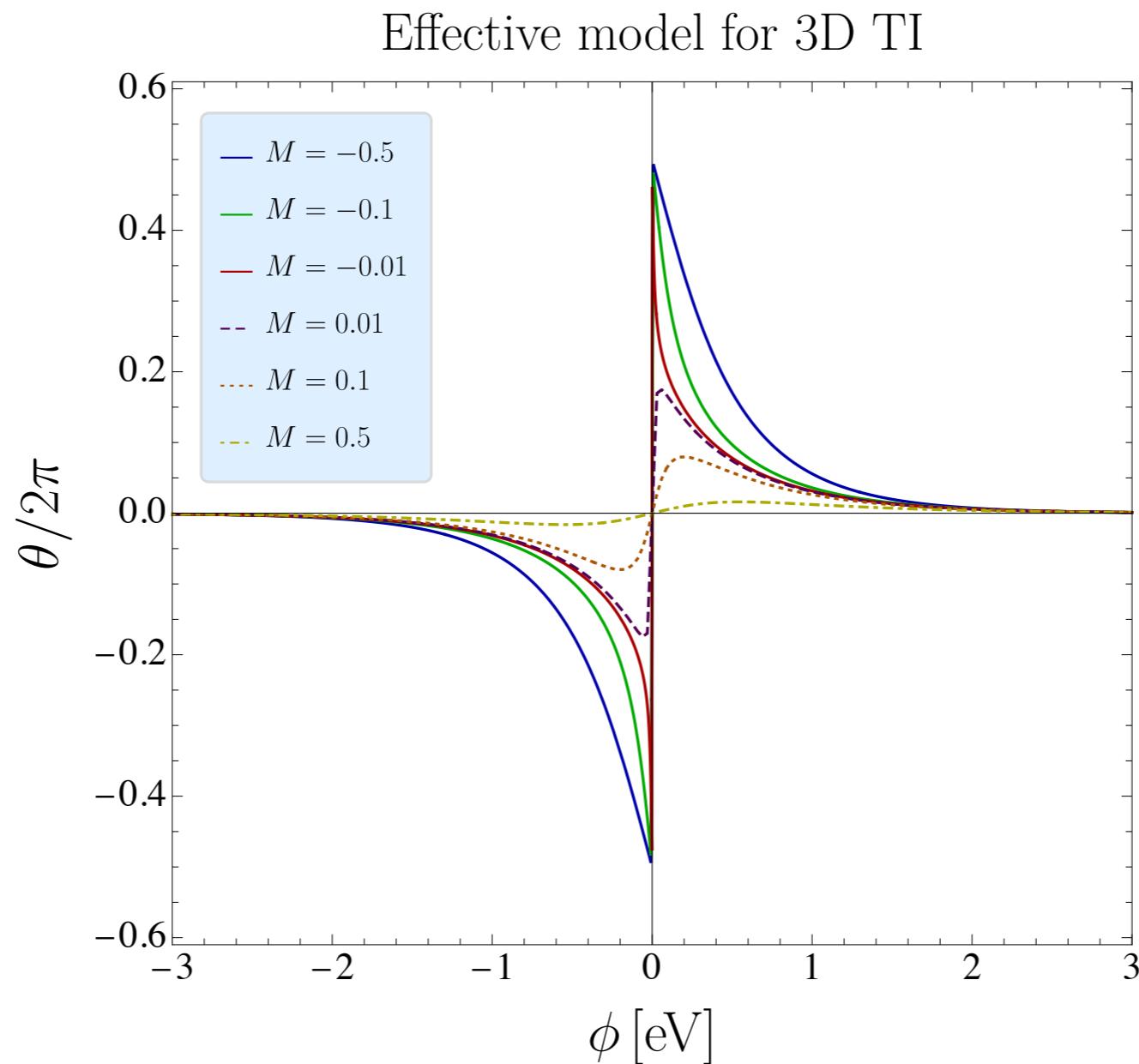
θ as function of M

KI '21

Effective model for 3D TI

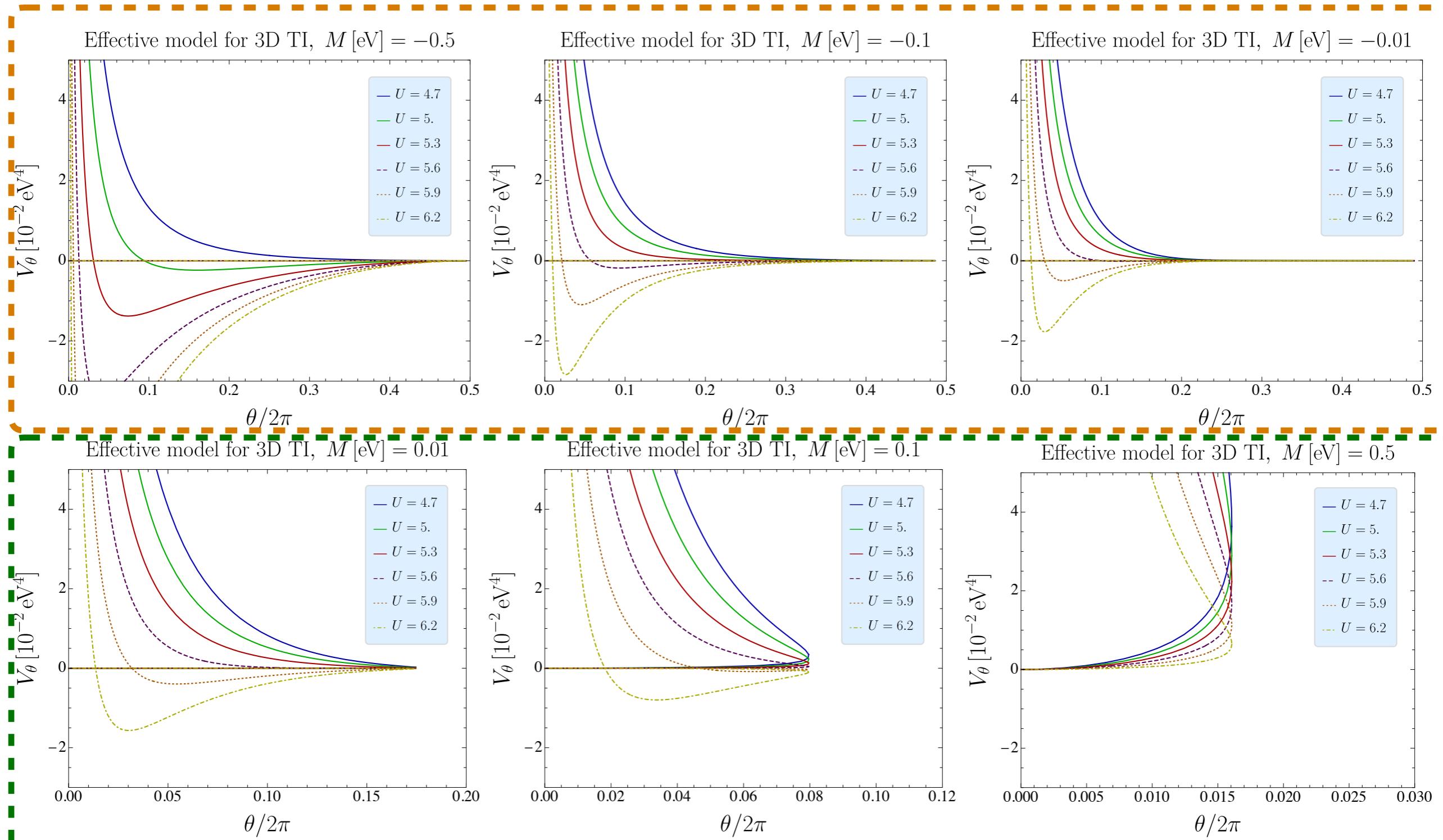


θ as function of ϕ

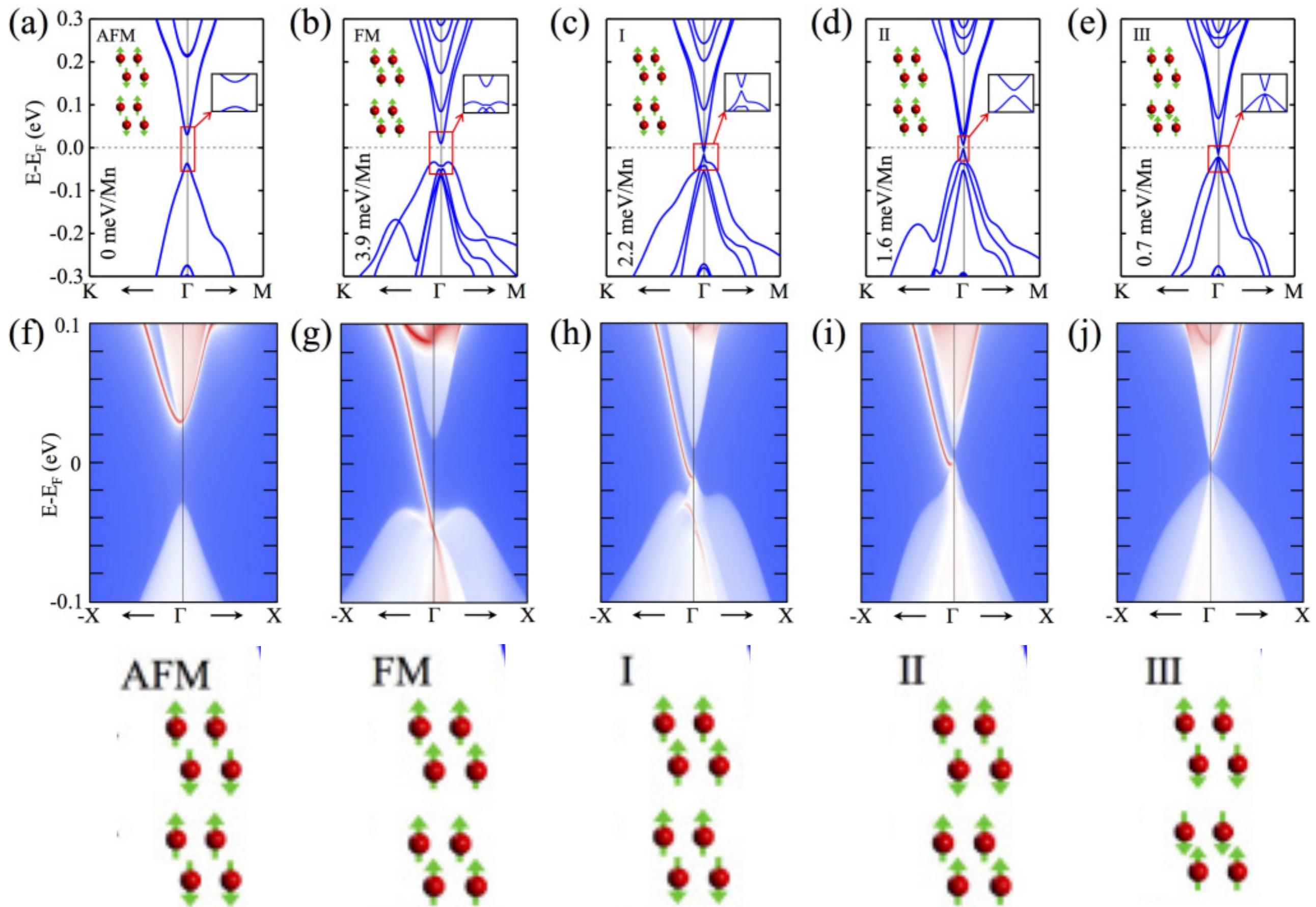


M dependence

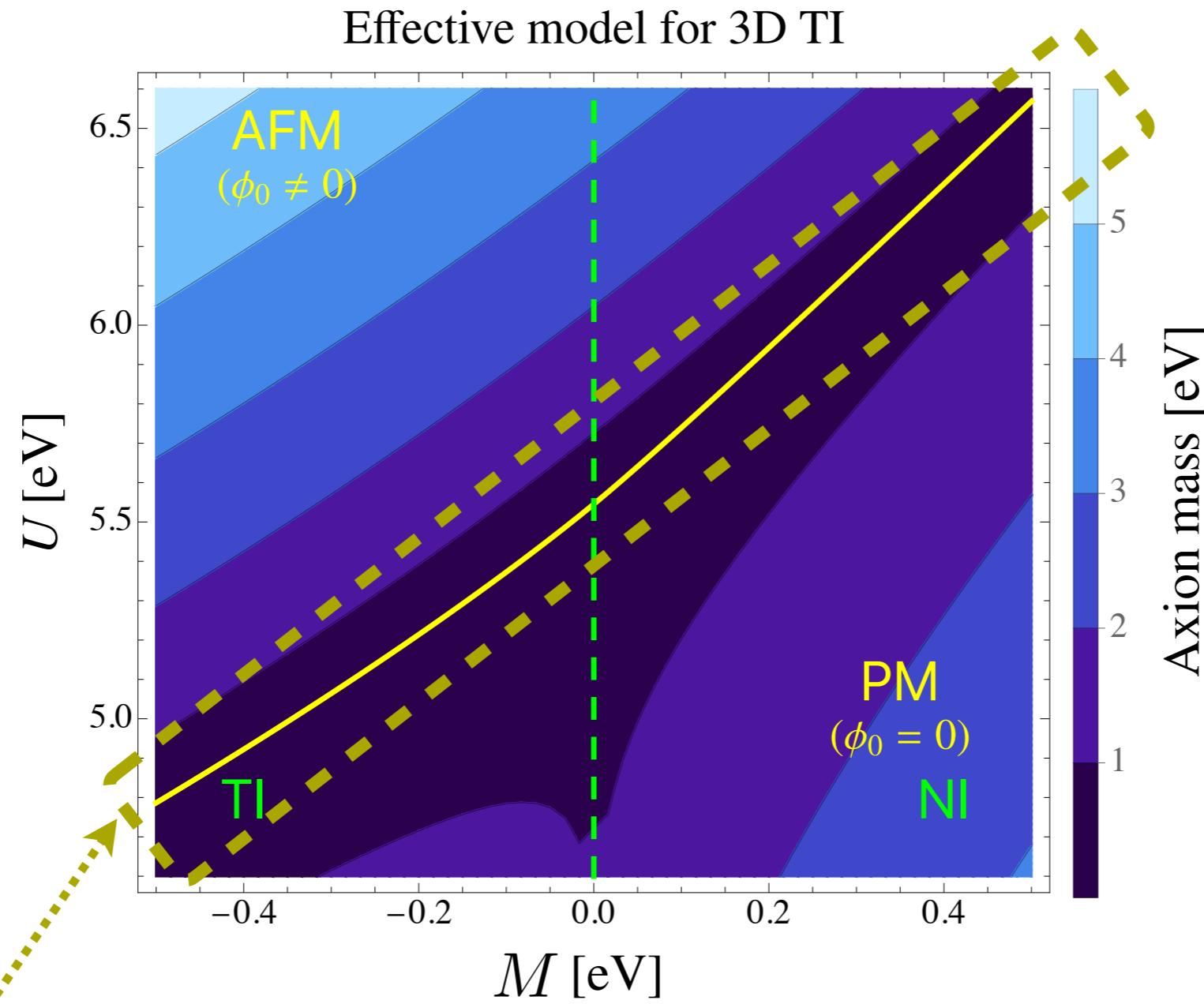
TI



NI



Axion mass



It can be suppressed
near the phase boundary

Rich magnetic topological
states in that region?